

# High-Voltage Power-Management IC for Automotive Safety Applications

Check for Samples: TPS65311-Q1

# **FEATURES**

- Qualified for Automotive Applications
- AEC-Q100 Test Guidance with the Following **Results:** 
  - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature
  - Device HBM ESD Classification Level H1B
  - Device CDM ESD Classification Level C3B
- Input Voltage Range: 4 V to 40 V, Transients up to 60 V; 80 V When Using External Pchannel Metal-Oxide Semiconductor (PMOS)
- Single-Output Synchronous-Buck Controller
  - Peak Gate-Drive Current 0.6 A
  - 490-kHz Fixed Switching Frequency
  - Pseudo Random Frequency-Hopping Spread Spectrum or Triangular Mode
- **Dual-Synchronous Buck Converter** 
  - Designed for Output Currents up to 2 A
  - Out of Phase Switching
  - Switching Frequency: 2.45 MHz
- Adjustable 350-mA Linear Regulator
- Adjustable Asynchronous-Boost Converter
  - 1-A Integrated Switch
  - Switching Frequency: 2.45 MHz
- Soft-Start Feature for All Regulator Outputs
- Independent Voltage Monitoring
- Undervoltage (UV) Detection and Overvoltage . (OV) Protection
- Short Circuit, Overcurrent, and Thermal Protection on Buck Controller, Gate Drive, Buck Converters, BOOST Converter, and Linear Regulator Outputs
- Serial-Peripheral Interface (SPI) for Control and Diagnostic
- Integrated Window Watchdog (WD)
- **Reference Voltage Output**
- High-Side (HS) Driver for Use with External

Field-Effect Transistor (FET), Light-Emitting **Diode (LED) Driver** 

- Input for External Temperature Sensor, Integrated Circuit (IC) Shutdown at T<sub>A</sub> < -40°C
- Thermally Enhanced PowerPAD<sup>™</sup> Package
  - 56-pin VQFN (RVJ)

## APPLICATIONS

- **Multi-Rail DC Power Distribution Systems**
- Safety-Critical Automotive Applications
  - Advanced Driver Assistance Systems

## DESCRIPTION

The TPS65311-Q1 device is a power-management unit, meeting the requirements of digital-signalprocessor (DSP) controlled-automotive systems (for example, Advanced Driver Assistance Systems). With the integration of commonly used features, the TPS65311-Q1 device significantly reduces board space and system costs.

The device includes one high-voltage buck controller for pre-regulation combined with a two-buck and oneboost converter for post regulation. A further integrated low-dropout (LDO) regulator rounds up the power-supply concept and offers a flexible system design with five independent-voltage rails. The device offers a low power state (LPM0 with all rails off) to reduce current consumption in case the system is constantly connected to the battery line. All outputs are protected against overload and over temperature.

An external PMOS protection feature makes the device capable of sustaining voltage transients up to 80 V. This external PMOS is also used in safetycritical applications to protect the system in case one of the rails shows a malfunction (undervoltage, overvoltage, or overcurrent).

Internal soft-start ensures controlled startup for all supplies. Each power-supply output has an adjustable output voltage based on the external resistor-network settings.



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# TPS65311-Q1



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.





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## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                          |                                 | MIN               | MAX                                      | UNIT |
|--------------------------|---------------------------------|-------------------|--|------|
|                          | VIN                             | -0.3              | 80                                       | V    |
|                          | VINPROT                         | -0.3              | 60                                       | V    |
| Supply inputs            | VSUP2, 3 (BUCK2 and 3)          | -0.3              | 20                                       | V    |
|                          | VSUP4 (Linear Regulator)        | -0.3              | 20                                       | V    |
|                          | VBOOST                          | -0.3              | 20                                       | V    |
|                          | EXTSUP                          | -0.3              | 13                                       | V    |
|                          | VIO                             | -0.3              | 5.5                                      | V    |
|                          | DI 14                           | -1                | 60                                       |      |
|                          | PH1                             | -2 for 100 ns     |  | V    |
|                          | VSENSE1                         | -0.3              | 20                                       | V    |
|                          | COMP1                           | -0.3              | 20                                       | V    |
| Buck controller          | GU-PH1, GL-PGND1, BOOT1-PH1     | -0.3              | 8  | V    |
|                          | S1, S2                          | -0.3              | 20                                       | V    |
|                          | S1-S2                           | -2                | 2  | V    |
|                          | BOOT1                           | -0.3              | 68                                       | V    |
|                          | VMON1                           | -0.3              | 20                                       | V    |
|                          | BOOT2, BOOT3                    | -1                | 20                                       | V    |
|                          |                                 | -1 <sup>(2)</sup> | 20 <sup>(2)</sup>                        |      |
| Buck controller          | PH2, PH3                        | –2 for 10 ns      |  | V    |
|                          | VSENSE2, VSENSE3                | -0.3              | 20                                       | V    |
|                          | COMP2, COMP3                    | -0.3              | 20                                       | V    |
|                          | VMON2, VMON3                    | -0.3              | 20                                       | V    |
|                          | BOOTx – PHx                     | -0.3              | 8  | V    |
|                          | LDO_OUT                         | -0.3              | 8  | V    |
| Linear regulator         | VSENSE4                         | -0.3              | 20                                       | V    |
|                          | VSENSE5                         | -0.3              | 20                                       | V    |
| Boost converter          | PH5                             | -0.3              | 20                                       | V    |
|                          | COMP5                           | -0.3              | 20                                       | V    |
| D                        | CSN, SCK, SDO, SDI, WD, HSPWM   | -0.3              | 5.5                                      | V    |
| Digital interface        | RESN, PRESN, IRQ                | -0.3              | 20                                       | V    |
| Wake input               | WAKE                            | -1 <sup>(3)</sup> | 60                                       | V    |
|                          | GPFET                           | -0.3              | 80                                       | V    |
| Protection FET           | VIN – GPFET                     | -0.3              | 20                                       | V    |
| <b>D</b>                 |                                 | -1 <sup>(3)</sup> | 60                                       | .,   |
| Battery sense input      | VSSENSE                         |                   | Transients up to 80 $V^{\left(4\right)}$ | V    |
| <b>T</b>                 | VT                              | -0.3              | 5.5                                      | V    |
| Temperature sense        | VT_REF                          | -0.3              | 20                                       | V    |
| Reference voltage        | VREF                            | -0.3              | 5.5                                      | V    |
|                          | HSSENSE                         | -0.3              | 60                                       | V    |
| High-side and LED driver | HSCTRL                          | -0.3              | 60                                       | V    |
|                          | VINPROT-HSSENSE, VINPROT-HSCTRL | -0.3              | 20                                       | V    |
| Driver supply decoupling | VREG                            | -0.3              | 8  | V    |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Maximum 3.5 A

(3)  $I_{max} = 100 \text{ mA}$ 

(4) Internally clamped to 60-V, 20-k $\Omega$  external resistor required, current into pin limited to 1 mA.

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# **ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup> (continued)**

over operating free-air temperature range (unless otherwise noted)

|                               |   |                   | MIN  | МАХ | UNIT |
|-------------------------------|---|-------------------|------|-----|------|
| Supply decoupling             | DVDD  |                   | -0.3 | 3.6 | V    |
|                               | Human body model (HBM) AEC-Q1<br>classification level H1B | 00                |      | 1   | kV   |
| Electrostatic discharge (ESD) |   | VT pin            |      | 150 |      |
| ratings                       |   | Corner pins       |      | 750 | V    |
|                               | AEC-Q100 classification level C3B                         | All other<br>pins |      | 500 | ·    |
|                               | Junction temperature: T <sub>J</sub>                      |                   | -55  | 150 |      |
| Tomporatura ratinga           | Operating temperature: T <sub>A</sub>                     |                   | -55  | 125 | °C   |
| Temperature ratings           | Storage temperature: T <sub>stg</sub>                     |                   | -55  | 165 | C    |
|                               | Lead temperature (Soldering, 10 se                        | c)                |      | 260 |      |

#### THERMAL INFORMATION

|                    | THERMAL METRIC <sup>(1)</sup>                | TPS65311-Q1   |        |
|--------------------|--|---|--------|
|                    |  | RVJ (56 PINS)           27           11.2           8           0.8 | UNIT   |
| $\theta_{JA}$      | Junction-to-ambient thermal resistance       | 27  |        |
| θ <sub>JCtop</sub> | Junction-to-case (top) thermal resistance    | 11.2  |        |
| $\theta_{JB}$      | Junction-to-board thermal resistance         | 8   | °C 11/ |
| $\Psi_{JT}$        | Junction-to-top characterization parameter   | 0.8   | °C/W   |
| Ψјв                | Junction-to-board characterization parameter | 4.9   |        |
| $\theta_{JCbot}$   | Junction-to-case (bottom) thermal resistance | 0.8   |        |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics Application Report, SPRA953.

## **RECOMMENDED OPERATING CONDITIONS**

over operating free-air temperature range (unless otherwise noted)

|    |  |   | MIN | TYP | MAX | UNIT |
|----|--|---|-----|-----|-----|------|
|    | Supply voltage at VIN, VINPROT, VSS    | SENSE   | 4.8 |     | 40  | V    |
| т  | Operating free air temperature renge   | All electrical characteristics in spec                      | -40 |     | 125 | °C   |
| IA | A Operating free air temperature range | Shutdown comparator and internal voltage regulators in spec | -55 |     | 125 |      |
| т  | Operating virtual junction             | All electrical characteristics in specification             |     |     | 125 | °C   |
| IJ | temperature range                      | Shutdown comparator and internal voltage regulators in spec |     |     | 125 | °C   |

**EXAS** 

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# **ELECTRICAL CHARACTERISTICS**

|                          | PARAMETER  | TEST CONDITIONS   | MIN  | TYP                   | MAX  | UNIT |
|--------------------------|--|---|------|-----------------------|------|------|
| INPUT VOLTAG             | E-CURRENT CONSUMPTION  |   |      |                       |      |      |
| V <sub>IN</sub>          | Device operating range   | Buck regulator operating range, Voltage on VIN and VINPROT pins   | 4    |                       | 50   | V    |
| V                        | Power-on reset threshold   | Falling VIN   | 3.5  | 3.6                   | 3.8  | V    |
| V <sub>POR</sub>         | Fower-on reset threshold   | Rising VIN  | 3.9  | 4.2                   | 4.3  | v    |
| V <sub>POR_hyst</sub>    | Power-on reset hysteresis on VIN   |   | 0.47 | 0.6                   | 0.73 | V    |
| I <sub>LPM0</sub>        | LPM0 current consumption <sup>(1)(2)</sup>   | All off, wake active, $V_{IN}$ = 13 V<br>Total current into VSSENSE, VIN and VINPROT  |      |                       | 44   | μA   |
| I <sub>LPM0</sub>        | LPM0 current (commercial vehicle application) consumption <sup>(3)(2)</sup>                                | All off, wake active, $V_{IN}$ = 24.5 V<br>Total current into VSSENSE, VIN and VINPROT  |      |                       | 60   | μA   |
| I <sub>ACTIVE1</sub>     | ACTIVE total current consumption <sup>(1)(4)</sup>   | $\begin{array}{l} BUCK1=on,V_{IN}=13\;V,EXTSUP=0\;V,Q_gof\\ BUCK1\;FETs=15\;nC.\\ Total\;current\;into\;VSSENSE,\;VIN\;and\;VINPROT array$  |      | 32                    |      | mA   |
| I <sub>ACTIVE123</sub>   | ACTIVE total current consumption <sup>(1)(4)</sup>   | $\begin{array}{l} BUCK1/2/3=on,V_{IN}=13V,\\ Q_{g}ofBUCK1FETs=15nC.\\ TotalcurrentintoVSSENSE,VINandVINPROT \end{array}$  |      | 40                    |      | mA   |
| ACTIVE1235               | ACTIVE current consumption <sup>(1)(4)</sup>   | $\begin{array}{l} BUCK1/2/3, LDO, BOOST, high-side switch = on, \\ V_{\text{IN}} = 13 \text{ V}, Q_{g} \text{ of BUCK1 FETs} = 15 \text{ nC}. \\ EXTSUP = 5 \text{ V} \text{ from BOOST} \\ Total current into VSSENSE, VIN and VINPROT \end{array}$    |      | 31                    |      | mA   |
| ACTIVE1235_noEXT         | ACTIVE current consumption <sup>(1)(4)</sup>   | $\begin{array}{l} BUCK1/2/3, LDO, BOOST, high-side switch = on, \\ V_{\text{IN}} = 13 \text{ V}, \text{ Q}_{g} \text{ of BUCK1 FETs} = 15 \text{ nC}, \text{ EXTSUP} = \\ \text{open} \\ \text{Total current into VSENSE, VIN and VINPROT} \end{array}$ |      | 53                    |      | mA   |
| BUCK CONTRO              | DLLER (BUCK1)  |   |      |                       |      |      |
| V <sub>BUCK1</sub>       | Adjustable output voltage range  |   | 3    |                       | 11   | V    |
| V <sub>Sense1_NRM</sub>  | Internal reference voltage in<br>operating mode  | VSENSE1 pin, load = 0 mA, Internal REF = 0.8 V  | -1%  |                       | 1%   |      |
| V <sub>S1-2</sub>        | VS1-2 for forward OC in CCM  | Maximum sense voltage VSENSE1 = 0.75 V (low duty cycle)   | 60   | 75                    | 90   | mV   |
| \$51-2                   |  | Minimum sense voltage VSENSE 1 = 1 V (negative current limit)   | -65  | -37.5                 | -23  | iiiv |
| A <sub>CS</sub>          | Current sense voltage gain   | $\Delta VCOMP1 / \Delta (VS1 - VS2)$  | 4    | 8                     | 12   |      |
| OCBUCK1_BLK              | RSTN and ERROR mode transition,<br>when over current detected for ><br><sup>t</sup> <sub>OCBUCK1 BLK</sub> |   |      | 1                     |      | ms   |
| DEAD_BUCK1               | Shoot-through delay, blanking time   |   |      | 25                    |      | ns   |
| SWBUCK1                  | Switching frequency  |   |      | f <sub>OSC</sub> / 10 |      |      |
|                          | Duty avala   | High-side minimum on time   |      | 100                   |      | ns   |
| DC                       | Duty cycle   | Maximum duty cycle  |      | 98.75%                |      |      |
| EXTERNAL NM              | OS GATE DRIVERS FOR BUCK CON   | TROLLER   |      |                       |      |      |
| Gpeak                    | Gate driver peak current   | VREG = 5.8 V  |      | 0.6                   |      | А    |
| R <sub>DSON_DRIVER</sub> | Source and sink driver   | $I_{G}$ current for external MOSFET = 200 mA, VREG = 5.8 V, $V_{BOOT1\text{-}PH1}$ = 5.8 V  |      | 5                     | 10   | Ω    |
| V <sub>DIO1</sub>        | Bootstrap diode forward voltage  | I <sub>BOOT1</sub> = -200 mA, VREG-BOOT1  | 0.8  |                       | 1.1  | V    |
| ERROR AMPLIF             | FIER (OTA) FOR BUCK CONTROLLE  | RS AND BOOST CONVERTER  |      |                       |      |      |
| EMPTY                    |  |   |      |                       |      |      |
| gm <sub>EA</sub>         | Forward transconductance   | COMP1/2/3/5 = 0.8 V; source/sink = 5 µA,<br>test in feedback loop   |      | 0.9                   |      | mmho |
| A <sub>EA</sub>          | Error amplifier DC gain  |   | 60   |                       |      | dB   |

(1)  $T_A = 25^{\circ}C$ (2) Quiescent Current Specification does not include the current flow through the external feedback resistor divider. Quiescent Current is non-switching current, measured with no load on the output with VBAT = 13V.

(3)  $T_A = 130^{\circ}C$ (4) Total current consumption measured on EVM includes switching losses.

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# ELECTRICAL CHARACTERISTICS (continued)

|                            | PARAMETER   | TEST CONDITIO  | DNS                                 | MIN           | TYP                  | MAX           | UNIT     |
|----------------------------|---|--|-------------------------------------|---------------|----------------------|---------------|----------|
| SYNCHRONOU                 | IS BUCK CONVERTER BUCK2/3                                   |  |                                     |               |                      |               |          |
| VSUP2/3                    | Supply voltage  |  |                                     | 3             |                      | 11            | V        |
| V <sub>BUCK2/3</sub>       | Regulated output voltage range                              | $I_{load}$ = 02 A<br>VSUPx = V <sub>BUCK2/3</sub> + $I_{load}$ × 0.2 Ω                           |                                     | 0.8           |                      | 5.5           | V        |
| R <sub>DSON-HS</sub>       | R <sub>DSON</sub> high-side switch                          | V <sub>BOOTx -PHx</sub> = 5.8 V  |                                     |               |                      | 0.20          | Ω        |
| R <sub>DSON-LS</sub>       | R <sub>DSON</sub> low-side switch                           | VREG = 5.8 V   |                                     |               |                      | 0.20          | Ω        |
| I <sub>HS-Limit</sub>      | High-side switch current limit                              | Static current limit test.   |                                     | 2.5           | 2.9                  | 3.3           |          |
| I <sub>LS-Limit</sub>      | Low-side switch current limit                               | In application L > 1 $\mu$ H at I <sub>HS-Limit</sub> and I <sub>LS-Limit</sub> to limit dI / dt |                                     | 2             | 2.5                  | 3             | A        |
| VSUP <sub>Lkg</sub>        | VSUP leakage current  | VSUP = 10 V for high side, control $T_J = 100^{\circ}C$  | ller disabled,                      |               | 1                    | 2             | μΑ       |
| f <sub>SWLBuck2/3</sub>    | Buck switching frequency                                    |  |                                     |               | f <sub>OSC</sub> / 2 |               |          |
| V <sub>Sense2/3</sub>      | Feedback voltage  | With respect to the 800-mV intern  | al reference                        | -1%           |                      | 1%            |          |
| DC <sub>BUCK2/3</sub>      | Duty cycle  | High-side minimum on time  |                                     |               | 50                   |               | ns       |
|                            |   | Maximum duty cycle   |                                     |               | 99.8%                |               |          |
| tDEAD_BUCK2/3              | Shoot-through delay   |  |                                     |               | 20                   |               | ns       |
| COMP2/3 <sub>HTH</sub>     | COMP2/3 Input threshold low                                 |  |                                     | 0.9           |                      | 1.5           | V        |
| COMP2/3 <sub>LTH</sub>     | COMP2/3 Input threshold high                                |  |                                     | VREG –<br>1.2 |                      | VREG –<br>0.3 | V        |
| R <sub>TIEOFF</sub> COMP23 | COMP2/3 internal tie-off                                    | BUCK2/3 enabled. Resistor to VR  | EG and GND, each                    | 70            | 100                  | 130           | kΩ       |
| V <sub>DIO2 3</sub>        | Bootstrap diode forward voltage                             | I <sub>BOOT1</sub> = -200 mA, VREG-BOOT2   | , VREG-BOOT3                        |               | 1.1                  | 1.2           | V        |
| BOOST CONVE                | ERTER   |  |                                     |               |                      |               |          |
| V <sub>Boost</sub>         | Boost adjustable output voltage range                       | Using 3.3-V input voltage, leak_sv   | witch ≤ 1 A                         | 4.5           |                      | 15            | V        |
| V <sub>Boost</sub>         | Boost adjustable output voltage range                       | Using 3.3-V input voltage I <sub>loadmax</sub> = 0.3 A   | = 20 mA, I <sub>peak_switch</sub> = | 15            |                      | 18.5          | V        |
| R <sub>DS-ON BOOST</sub>   | Internal switch on-resistance                               | VREG = 5.8 V   |                                     |               | 0.3                  | 0.5           | Ω        |
| V <sub>Sense5</sub>        | Feedback voltage  | With respect to the 800-mV intern  | al reference                        | -1%           |                      | 1%            |          |
| f <sub>SWLBOOST</sub>      | Boost switching frequency                                   |  |                                     |               | f <sub>OSC</sub> / 2 |               |          |
| DC <sub>BOOST</sub>        | Maximum internal MOSFET duty cycle at f <sub>SWLBOOST</sub> |  |                                     |               | 75%                  |               |          |
| ICLBOOST                   | Internal switch current limit                               |  |                                     | 1             |                      | 1.5           | А        |
| LINEAR REGUI               | LATOR LDO   |  |                                     |               |                      |               |          |
| VSUP4                      | Device operating range for LDO                              | Recommended operating range  |                                     | 3             |                      | 7             | V        |
| V <sub>LDO</sub>           | Regulated output range                                      | I <sub>OUT</sub> = 1 mA to 350 mA  |                                     | 0.8           |                      | 5.25          | V        |
| V <sub>RefLDO</sub>        | DC output voltage tolerance at<br>VSENSE4                   | VSENSE4 = 0.8 V (regulated at in<br>VSUP4 = 3 V to 7 V, I <sub>OUT</sub> = 1 mA                  | ,                                   | -2%           |                      | 2%            |          |
| V <sub>step1</sub>         | Load step 1   | VSENSE4 = 0.8 V (regulated at in $I_{OUT}$ = 1 mA to 101 mA, $C_{LDO}$ = 6                       | iternal ref)                        | -2%           |                      | 2%            |          |
| V <sub>Sense4</sub>        | Feedback voltage  | With respect to the 800-mV intern  |                                     | -1%           |                      | 1%            |          |
|                            | Drop out voltage  | I <sub>OUT</sub> = 350 mA, T <sub>J</sub> = 25°C   |                                     |               | 127                  | 143           | mV       |
| V <sub>Dropout</sub>       | Drop our voltage  | $I_{OUT}$ = 350 mA, $T_J$ = 125°C  |                                     |               | 156                  | 180           | 111V     |
| I <sub>OUT</sub>           | Output current  | V <sub>OUT</sub> in regulation   |                                     | -350          |                      | -1            | mA       |
| I <sub>LDO-CL</sub>        | Output current limit  | $V_{OUT}$ = 0 V, VSUP4 = 3 V to 7 V  |                                     | -1000         |                      | -400          | mA       |
|                            |   |  | Freq = 100 Hz                       |               | 60                   |               |          |
| PSRR <sub>LDO</sub>        | Power supply ripple rejection                               | $V_{ripple} = 0.5 V_{PP}, I_{OUT} = 300 \text{ mA},$<br>$C_{LDO} = 10 \mu \text{F}$              | Freq = 4 kHz                        |               | 50                   |               | dB       |
|                            |   |  | Freq = 150 kHz                      |               | 25                   |               |          |
| LDOns <sub>10-100</sub>    | Output noise 10 Hz – 100 Hz                                 | 10- $\mu$ F output capacitance, V <sub>LDO</sub> =   | 2.5 V                               |               |                      | 20            | µV/√(Hz) |
| LDOns <sub>100-1k</sub>    | Output noise 100 Hz – 10 kHz                                | 10- $\mu$ F output capacitance, V <sub>LDO</sub> =   | 2.5 V                               |               |                      | 6             | µV/√(Hz) |
| C <sub>LDO</sub>           | Output capacitor  | Ceramic capacitor with ESR range 100 mΩ  | e, $C_{LDO_{ESR}} = 0$ to           | 6             |                      | 50            | μF       |



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# ELECTRICAL CHARACTERISTICS (continued)

|                         | PARAMETER   | TEST CONDITIONS  | MIN                 | TYP        | MAX      | UNIT                      |
|-------------------------|---|--|---------------------|------------|----------|---------------------------|
| LED AND HIGH            | H-SIDE SWITCH CONTROL                               |  |                     |            |          |                           |
| V <sub>HSSENSE</sub>    | Current sense voltage                               | VINPROT – HSSENSE, high-side switch in current limit   | 370                 | 400        | 430      | mV                        |
| VCM <sub>HSSENSE</sub>  | Common mode range for current sensing               | See VINPROT  | 4                   |            | 60       | V                         |
| V <sub>HSOL_TH</sub>    | VINPROT – HSSENSE open load threshold               | Ramping negative   | 5                   | 20         | 35       | mV                        |
|                         |   | Ramping positive   | 26                  | 38         | 50       |                           |
| V <sub>HSOL_HY</sub>    | Open load hysteresis                                |  | 10                  | 18         | 28       | mV                        |
| t <sub>HSOL_BLK</sub>   | Open load blanking time                             |  | 70                  | 100        | 140      | μs                        |
| V <sub>HS SC</sub>      | VINPROT – HSSENSE load short<br>detection threshold | Ramping positive<br>Ramping negative from load short condition   | 88<br>87            | 92.5<br>90 | 96<br>93 | %<br>V <sub>HSSENSE</sub> |
| V <sub>HSSC_HY</sub>    | VINPROT – HSSENSE short circuit<br>hysteresis       |  | 1.5                 | 2.5        | 3.5      | %<br>V <sub>HSSENSE</sub> |
| t <sub>HSS CL</sub>     | Net time in current limit to disable driver         |  | 4                   | 5          | 6        | ms                        |
| t <sub>s Hs</sub>       | Current limit sampling interval                     |  |                     | 100        |          | μs                        |
| VHSCTRL <sub>OFF</sub>  | Voltage at HSCTRL when OFF                          |  | VINPRO<br>T<br>-0.5 |            | VINPROT  | V                         |
| V <sub>GS</sub>         | Clamp voltage between<br>HSSENSE – HSCTRL           |  | 6.1                 | 7.7        | 8.5      | V                         |
|                         |   | Time from rising HSPWM till high-side switch in<br>current limitation, ±5% settling                                      |                     |            | 30       | μs                        |
| t <sub>ON</sub>         | Turn on time  | Time from rising HSPWM till high-side switch till voltage-clamp between HSSENSE – HSCTRL active (within $V_{GS}$ limits) |                     | 30         | 60       | μs                        |
| V <sub>OS_HS</sub>      | Overshoot during turn-on                            | V <sub>OS_HS</sub> = VINPROT - HSSENSE   |                     |            | 400      | mV                        |
| I <sub>CL_HSCTRL</sub>  | HSCTRL current limit                                |  | 2                   | 4.1        | 5        | mA                        |
| R <sub>PU_HSCTRL</sub>  |   | Between VINPROT and HSCTRL   |                     |            |          |                           |
| R <sub>PU_HSCTRL</sub>  | Internal pull-up resistors                          | Between HSCTRL and HSSENSE   | 70                  | 100        | 130      | kΩ                        |
| V <sub>I_high</sub>     | High level input voltage                            | HSPWM, VIO = 3.3 V   | 2                   |            |          | V                         |
| V <sub>I_low</sub>      | Low level input voltage                             | HSPWM, VIO = 3.3 V   |                     |            | 0.8      | V                         |
| V <sub>I_hys</sub>      | Input voltage hysteresis                            | HSPWM, VIO = 3.3 V   | 150                 |            | 500      | mV                        |
| f <sub>HS_IN</sub>      | HSPWM input frequency                               | Design info, no device parameter   | 100                 |            | 500      | Hz                        |
| R <sub>SENSE</sub>      | External sense resistor                             | Design info, no device parameter   | 1.5                 |            | 50       | Ω                         |
| C <sub>GS</sub>         | External MOSFET gate source<br>capacitance          |  | 100                 |            | 2000     | pF                        |
| C <sub>GD</sub>         | External MOSFET gate drain<br>capacitance           |  |                     |            | 500      | pF                        |
| REFERENCE \             | /OLTAGE   |  |                     |            |          |                           |
| V <sub>REF</sub>        | Reference voltage                                   |  |                     | 3.3        |          | V                         |
| V <sub>REF-tol</sub>    | Reference voltage tolerance                         | I <sub>VREF</sub> = 5 mA   | -1%                 |            | 1%       |                           |
| IREFCL                  | Reference voltage current limit                     |  | 10                  |            | 25       | mA                        |
| C <sub>VREF</sub>       | Capacitive load                                     |  | 0.6                 |            | 5        | μF                        |
| REFns <sub>10-100</sub> | Output noise 10 Hz–100 Hz                           | 2.2 µF output capacitance, I <sub>VREF</sub> = 5 mA  |                     |            | 20       | µV/√(Hz)                  |
| REFns <sub>100-1k</sub> | Output noise 100 Hz–10 kHz                          | 2.2 $\mu$ F output capacitance, I <sub>VREF</sub> = 5 mA   |                     |            | 6        | μV/√(Hz)                  |
|                         | -   | Threshold, V <sub>REF</sub> falling  | 2.91                | 3.07       | 3.12     | V                         |
| V <sub>REF_OK</sub>     | Reference voltage OK threshold                      | Hysteresis   | 14                  | 70         | 140      | mV                        |
| T <sub>REF_OK</sub>     | Reference voltage OK deglitch time                  |  | 10                  |            | 20       | μs                        |

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# **ELECTRICAL CHARACTERISTICS (continued)**

|                          | PARAMETER   | TEST CONDITIONS   | MIN  | TYP  | MAX    | UNIT   |
|--------------------------|---|---|------|------|--------|--------|
| SHUTDOWN C               | OMPARATOR   |   |      |      |        |        |
|                          | Shutdown comparator reference   | $I_{VT\_REF}$ = 20 µA. Measured as drop voltage with respect to VDVDD                                       | 10   | 17   | 500 m' | m)/    |
| VT_REF                   | voltage   | $I_{VT_{REF}}$ = 600 µA. Measured as drop voltage with respect to VDVDD. No VT_REF short-circuit detection. | 200  | 420  | 1100   | mv     |
| I <sub>VT_REFCL</sub>    | Shutdown comparator reference<br>current limit                          | VT_REF = 0  | 0.6  | 1    | 1.4    | mA     |
| V <sub>VT_REF SH</sub>   | VT_REF short circuit detection  | Threshold, VT_REF falling. Measured as drop voltage with respect to VDVDD                                   | 0.9  | 1.2  | 1.8    | V      |
|                          |   | Hysteresis  |      | 130  |        | mV     |
| VT <sub>TH-H</sub>       | Input voltage threshold on VT, rising edge triggers shutdown            | This feature is specified by design to work down to –55°C.  | 0.48 | 0.50 | 0.52   | VT_REF |
| VT <sub>TH-L</sub>       | Input voltage threshold on VT, falling voltage enables device operation | This feature is specified by design to work down to<br>-55°C.   | 0.46 | 0.48 | 0.52   | VT_REF |
| VT <sub>TOL</sub>        | Threshold variation   | VT <sub>TH-H</sub> – VT_REF / 2, VT <sub>TH-L</sub> – VT_REF / 2  | -20  |      | 20     | mV     |
|                          |   | T <sub>J</sub> : –20°C to 125°C   | -400 |      | -50    | r^     |
| I <sub>VT_leak</sub>     | Leakage current   | T <sub>J</sub> : -55°C to -20°C   | -200 |      | -50    | nA     |
| VT_REF <sub>OV</sub>     | VT_REF overvoltage threshold  | Threshold, VT_REF rising. Measured as drop voltage with respect to VDVDD                                    | 0.42 | 0.9  | 1.2    | V      |
| _ 01                     | _ 0   | Hysteresis  |      | 100  |        | mV     |
| T <sub>VT_REF_FLT</sub>  | VT_REF fault deglitch time  | Overvoltage or short condition on VT_REF  | 10   |      | 20     | μs     |
| WAKE INPUT               |   |   |      |      |        |        |
| V <sub>WAKE_ON</sub>     | Voltage threshold to enable device                                      | WAKE pin is a level sensitive input   | 3.3  |      | 3.7    | V      |
| t <sub>WAKE</sub>        | Min. pulse width at WAKE to enable device                               | $V_{WAKE}$ = 4 V to suppress short spikes at WAKE pin   | 10   |      | 20     | μs     |
| VBAT UNDER               | VOLTAGE WARNING   |   |      |      |        |        |
| V <sub>SSENSETH_L</sub>  | VSSENSE falling threshold low   | SPI selectable, default after reset   | 4.3  |      | 4.7    | V      |
| V <sub>SSENSETH_H</sub>  | VSSENSE falling threshold high  | SPI selectable  | 6.2  |      | 6.8    | V      |
| V <sub>SSENSE-HY</sub>   | VSSENSE hysteresis  |   |      | 0.2  |        | V      |
| t <sub>VSSENSE_BLK</sub> | Blanking time   | $V_{VSENSE} < V_{SSENSETH xx} \rightarrow IRQ$ asserted   | 10   |      | 20     | μs     |
| IVSLEAK                  | Leakage current at VSSENSE  | LPM0 mode, VSSENSE 55 V   |      |      | 1      | μA     |
| IVSLEAK60                | Leakage current at VSSENSE  | LPM0 mode, VSSENSE 60 V   |      |      | 100    | μA     |
| I <sub>VSLEAK80</sub>    | Leakage current at VSSENSE  | LPM0 mode, VSSENSE 80 V   | 5    |      | 25     | mA     |
| R <sub>VSSENSE</sub>     | Internal resistance from VSSENSE to GND                                 | VSSENSE = 14 V, disabled in LPM0 mode   | 0.7  | 1    | 1.3    | MΩ     |
| VIN OVERVOL              | TAGE PROTECTION   | L   |      |      |        |        |
| V <sub>OVTH_H</sub>      | VIN overvoltage shutdown threshold 1 (rising edge)                      | Selectable with SPI   | 50   |      | 60     | V      |
| V <sub>OVTH_L</sub>      | VIN overvoltage shutdown threshold 2 (rising edge)                      | Selectable with SPI, default after reset  | 36   |      | 38     | V      |
|                          |   | Threshold 1   | 0.2  | 1.7  | 3      |        |
| V <sub>OVHY</sub>        | VIN overvoltage hysteresis  | Threshold 2 - default after reset   | 1.5  | 2    | 2.5 V  | V      |
| t <sub>OFF BLK-H</sub>   | OV delay time   | $VIN > V_{OVTH_H} \rightarrow GPFET \text{ off}$  |      | 1    |        | μs     |
| t <sub>OFF BLK-L</sub>   | OV blanking time  | $VIN > V_{OVTH L} \rightarrow GPFET off$  | 10   |      | 20     | μs     |



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# **ELECTRICAL CHARACTERISTICS (continued)**

|                            | PARAMETER   | TEST CONDITIONS  | MIN  | TYP                 | MAX  | UNIT |
|----------------------------|---|--|------|---------------------|------|------|
| WINDOW WAT                 | CHDOG   |  |      |                     |      |      |
| t <sub>timeout</sub>       | Timeout   | TESTSTART, TESTSTOP, VTCHECK , and RAMP<br>mode:<br>Starts after entering each mode.<br>ACTIVE mode:<br>WD timeout starts with rising edge of RESN | 230  | 300                 | 370  | ms   |
|                            |   | Spread spectrum disabled   | 18   | 20                  | 22   |      |
| t <sub>WD</sub>            | Watchdog window time                                    | Spread spectrum enable   | 19.8 | 22                  | 24.2 | ms   |
| t <sub>WD_FAIL</sub>       | Closed window time                                      |  |      | t <sub>WD</sub> / 4 |      |      |
| t <sub>WD_BLK</sub>        | WD filter time  |  |      |                     | 0.5  | μs   |
| V <sub>I_high</sub>        | High level input voltage                                |  | 2    |                     |      | V    |
| V <sub>I_low</sub>         | Low level input voltage                                 | WD, VIO = 3.3 V  |      |                     | 0.8  | V    |
| V <sub>I_hys</sub>         | Input voltage hysteresis                                |  | 150  |                     | 500  | mV   |
| RESET AND IR               | Q BLOCK   |  |      |                     |      |      |
| t <sub>RESNHOLD</sub>      | RESN hold time  |  | 1.8  | 2                   | 2.2  | ms   |
| V <sub>RESL</sub>          | Low level output voltage at RESN, PRESN and IRQ         | VIN ≥ 3 V, IxRESN = 2.5 mA   | 0    |                     | 0.4  | V    |
| V <sub>RESL</sub>          | Low level output voltage at RESN and PRESN              | VIN = 0 V, VIO = 1.2 V, IxRESN = 1 mA  | 0    |                     | 0.4  | V    |
| I <sub>RESLeak</sub>       | Leakage current at RESN, PRESN and IRQ                  | V <sub>test</sub> = 5.5 V  |      |                     | 1    | μA   |
| N <sub>RES</sub>           | Number of consecutive reset events for transfer to LPM0 |  |      | 7                   |      |      |
| t <sub>IRQHOLD</sub>       | IRQ hold time   | After V <sub>VSENSE</sub> < V <sub>SSENSETH</sub> for t <sub>VSSENSE_BLK</sub>   | 10   |                     | 20   | μs   |
| t <sub>DR IRQ PRESN</sub>  | Rising edge delay of IRQ to rising<br>edge of PRESN     |  |      | 2                   |      | μs   |
| t <sub>DF RESN_PRESN</sub> | Falling edge delay of RESN to<br>PRESN / IRQ            |  |      | 2                   |      | μs   |
| EXTERNAL PR                | OTECTION  |  |      |                     |      |      |
| VCLAMP                     | Gate to source clamp voltage                            | VIN - GPFET, 100 μA  | 14   |                     | 20   | V    |
| IGPFET                     | Gate turn on current                                    | VIN = 14 V, GPFET = 2 V  | 15   |                     | 25   | μA   |
| RDSONGFET                  | Gate driver strength                                    | VIN = 14 V, turn off   |      |                     | 25   | Ω    |
| THERMAL SHU                | JTDOWN AND OVERTEMPERATURE                              | PROTECTION   |      |                     |      |      |
| T <sub>SDTH</sub>          | Thermal shutdown  | Junction temperature   | 160  | 175                 |      | °C   |
| T <sub>SDHY</sub>          | Hysteresis  |  |      | 20                  |      | °C   |
| t <sub>SD-BLK</sub>        | Blanking time before thermal shutdown                   |  | 10   |                     | 20   | μs   |
| Т <sub>оттн</sub>          | Overtemperature flag                                    | Overtemperature flag is implemented as local temp<br>sensors and expected to trigger before the thermal<br>shutdown                                | 150  | 165                 |      | °C   |
| T <sub>OTHY</sub>          | Hysteresis  |  |      | 20                  |      | °C   |
| t <sub>OT_BLK</sub>        | Blanking time before thermal over temperature           |  | 10   |                     | 20   | μs   |

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**EXAS** 

# **ELECTRICAL CHARACTERISTICS (continued)**

|                                 | PARAMETER  | TEST CONDITIONS  | MIN        | ТҮР      | MAX        | UNIT    |
|---------------------------------|--|--|------------|----------|------------|---------|
| VOLTAGE MON                     | NITORS BUCK1/2/3, VIO, LDO, BOOS   | TER  |            |          |            |         |
| V <sub>MONTH_L</sub>            | Voltage monitor reference  | REF = 0.8 V – falling edge   | 90         | 92       | 94         | %       |
| V <sub>MONTH_H</sub>            | Voltage monitor reference  | REF = 0.8 V – rising edge  | 106        | 108      | 110        | %       |
| V <sub>MON_HY</sub>             | Voltage monitor hysteresis   |  |            | 2        |            | %       |
| V <sub>VIOMON_TH</sub>          | Undervoltage monitoring at VIO –<br>falling edge   |  | 3          |          | 3.13       | V       |
| V <sub>VIOMON_HY</sub>          | UV_VIO hysteresis  |  |            | 0.05     |            | V       |
| t <sub>VMON_BLK</sub>           | Blanking time between UV/OV<br>condition to RESN low   | UV/OV: BUCK1/2/3 UV: VIO   | 10         |          | 20         | μs      |
| t <sub>vmonthl_blk</sub>        | Blanking time between undervoltage<br>condition to ERROR mode transition<br>or corresponding SPI bit | $BUCK1/2/3 \to ERROR$ mode LDO or $BOOST \to SPI$ bit set or turn off  |            | 1        |            | ms      |
| tvmonthl_blk1                   | Blanking time between undervoltage<br>condition to ERROR mode transition                             | VIO only   | 10         |          | 20         | μs      |
| t <sub>VMONTHH_BLK1</sub>       | Blanking time between overvoltage<br>condition to ERROR mode transition                              | $\begin{array}{l} BUCK1/2/3 \rightarrow ERROR \text{ mode VIO has no OV} \\ protection \end{array}$                  | 10         |          | 20         | μs      |
| t <sub>VMONTHH_BLK2</sub>       | Blanking time LDO and BOOST<br>overvoltage condition to<br>corresponding SPI bit or ERROR<br>mode    | LDO or BOOST (ACTIVE mode) $\rightarrow$ SPI bit set or turn off LDO (VTCHECK or RAMP mode) $\rightarrow$ ERROR mode | 20         |          | 40         | μs      |
| GND LOSS                        |  |  |            |          |            |         |
| V <sub>GLTH-low</sub>           | GND loss threshold low   | GND to PGNDx   | -0.31      | -0.25    | -0.19      | V       |
| V <sub>GLTH-high</sub>          | GND loss threshold high  | GND to PGNDx   | 0.19       | 0.25     | 0.31       | V       |
| t <sub>GL-BLK</sub>             | Blanking time between GND loss<br>condition and transition to ERROR<br>state                         |  | 10         |          | 20         | μs      |
| POWER-UP SE                     | QUENCING   |  |            |          |            |         |
| t <sub>START1</sub>             | Soft start time of BOOST   | From start till exceeding V <sub>MONTH_L</sub> + V <sub>MON_HY</sub> Level   | 0.7        |          | 2.7        | ms      |
| t <sub>START2</sub>             | Soft start time of BUCK1/2/3 and LDO   | From start till exceeding $V_{MONTH_L}$ + $V_{MON_HY}$ Level   | 0.5        |          | 2          | ms      |
| t <sub>start</sub>              | Startup DVDD regulator   | From start till exceeding V <sub>MONTH_L</sub> + V <sub>MON_HY</sub> Level   |            |          | 3          | ms      |
| t <sub>SEQ2</sub>               | Sequencing time from start of<br>BUCK1 to BUCK2 and BOOST  | Internal SSDONE_BUCK1 signal   |            |          | 3          | ms      |
| t <sub>WAKE-RES</sub>           | Startup time from entering<br>TESTSTART to RESN high   | GPFET = IRFR6215   |            |          | 14         | ms      |
| t <sub>SEQ1</sub>               | Sequencing time from start of<br>BOOST to BUCK3  | Internal SSDONE_BOOST signal   | 1          |          | 4          | ms      |
| INTERNAL VOI                    | TAGE REGULATORS — T <sub>J(max)</sub> = 125  | °C   |            |          |            |         |
| V <sub>REG</sub>                | Internal regulated supply  | $I_{VREG}$ = 0 mA to 50 mA, VINPROT = 6.3 V to 40 V and EXTSUP = 6.3 V to 12 V                                       | 5.5        | 5.8      | 6.1        | V       |
| V <sub>EXTSUP-TH</sub>          | Switch over voltage  | $I_{\text{VREG}}$ = 0 mA to 50 mA and EXTSUP ramping positive, ACTIVE mode   | 4.4        | 4.6      | 4.8        | V       |
| V <sub>EXTSUP-HY</sub>          | Switch over hysteresis   |  | 100        | 200      | 300        | mV      |
| V <sub>REGDROP</sub>            | Drop out voltage on VREG   | I <sub>VREG</sub> = 50 mA,<br>EXTSUP = 5 V / VINPROT = 5 V and<br>EXTSUP = 0 V / VINPROT = 4 V                       |            |          | 200        | mV      |
| I <sub>REG_CL</sub>             |  | EXTSUP = 0 V, VREG = 0 V   | -250       |          | -50        | mA      |
| -<br>I <sub>REG_EXTSUP_CL</sub> | - Current limit on VREG  | EXTSUP ≥ 4.8 V, VREG = 0 V   | -250       |          | -50        | mA      |
| C <sub>VREG</sub>               | Capacitive load  |  | 1.2        | 2.2      | 3.3        | μF      |
| V <sub>REG-OK</sub>             | VREG undervoltage threshold  | VREG rising<br>Hysteresis  | 3.8<br>350 | 4<br>420 | 4.2<br>490 | V<br>mV |
| VDVDD                           | Internal regulated low voltage supply  |  | 3.15       | 3.3      | 3.45       | V       |
| VDVDD UV                        | DVDD undervoltage threshold  | DVDD falling   | 2.1        | 3.3      | 5.40       | V       |
| VDVDD OV                        | DVDD undervoltage threshold  | DVDD raining DVDD rising   | 2.1        |          | 3.8        | V       |
|                                 | Blanking time from DVDD<br>overvoltage condition to shutdown<br>mode transition                      | s s s s nong   | 10         |          | 20         | μs      |



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# ELECTRICAL CHARACTERISTICS (continued)

VIN = VINPROT 4.8 V to 40 V, VSUPx = 3 V to 5.5 V, EXTSUP = 0 V, T<sub>J(max)</sub> = 125°C, unless otherwise noted

|                      | PARAMETER  | TEST CONDITIONS                       | MIN                       | TYP  | MAX              | UNIT |
|----------------------|--|---------------------------------------|---------------------------|------|------------------|------|
| SPI INTERF           | ACE  |                                       |                           |      |                  |      |
| t <sub>SPI</sub>     | SCK period   |                                       | 240                       |      |                  | ns   |
| t <sub>SCKL</sub>    | SCK low time   |                                       | 100                       |      |                  | ns   |
| t <sub>scкн</sub>    | SCK high time  |                                       | 100                       |      |                  | ns   |
| t <sub>FSIV</sub>    | Time between falling edge of CSN and SDO output valid (FSI bit)                | Falling SDO < 0.8 V; Rising SDO > 2 V |                           |      | 80               | ns   |
| t <sub>SDOV</sub>    | Time between rising edge of SCK and SDO data valid                             | Falling SDO < 0.8 V; Rising SDO > 2 V |                           |      | 55               | ns   |
| t <sub>SDIS</sub>    | Setup time of SDI before falling<br>edge of SCK                                |                                       | 20                        |      |                  | ns   |
| t <sub>SDOH</sub>    | Hold time of SDO after rising edge<br>of SCK                                   |                                       | 5                         |      |                  | ns   |
| t <sub>HCS</sub>     | Hold time of CSN after last falling edge of SCK                                |                                       | 50                        |      |                  | ns   |
| t <sub>SDOtri</sub>  | Delay between rising edge of CSN and SDO 3-state                               |                                       |                           |      | 80               | ns   |
| t <sub>min2SPI</sub> | Minimum time between two SPI commands  |                                       | 10                        |      |                  | μs   |
| V <sub>I_high</sub>  | High level input voltage   | CSN, SCK, SDI; VIO = 3.3 V            | 2                         |      |                  | V    |
| V <sub>I_low</sub>   | Low level input voltage  | CSN, SCK, SDI; VIO = 3.3 V            |                           |      | 0.8              | V    |
| V <sub>I_hys</sub>   | Input voltage hysteresis   | CSN, SCK, SDI; VIO = 3.3 V            | 150                       |      | 500              | mV   |
| V <sub>O_high</sub>  | SDO output high voltage  | $VIO = 3.3 V I_{SDO} = 1 mA$          | 3                         |      |                  | V    |
| V <sub>O_low</sub>   | SDO output low voltage   | $VIO = 3.3 V I_{SDO} = 1 mA$          |                           |      | 0.2              | V    |
| CSDO                 | SDO capacitance  |                                       |                           |      | 50               | pF   |
| GLOBAL PA            | RAMETERS   |                                       |                           |      |                  |      |
| R <sub>PU</sub>      | Internal pullup resistor at CSN pin  |                                       | 70                        | 100  | 130              | kΩ   |
| R <sub>PD</sub>      | Internal pulldown resistor at pins:<br>HSPWM , SDI, SCK, WD, S2 <sup>(5)</sup> |                                       | 70                        | 100  | 130              | kΩ   |
| R <sub>PD-WAKE</sub> | Internal pulldown resistor at WAKE pin   |                                       | 140                       | 200  | 260              | kΩ   |
| I <sub>LKG</sub>     | Input pullup current at pins:<br>- VSENSE1–5<br>- VMON1–3                      | V <sub>TEST</sub> = 0.8 V             | -200                      | -100 | -50              | nA   |
| f <sub>osc</sub>     | Internal oscillator used for Buck or<br>Boost switching frequency              |                                       | 4.6                       | 4.9  | 5.2              | MHz  |
| f <sub>spread</sub>  | Spread spectrum frequency range  |                                       | 0.8 ×<br>f <sub>osc</sub> |      | f <sub>OSC</sub> |      |

#### (5) RAMP and ACTIVE only



## Figure 1. SPI Timing

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#### **PIN FUNCTIONS**

| PIN PULL UP / |     | I/O <sup>(1)</sup> | DESCRIPTION |   |
|---------------|-----|--------------------|-------------|---|
| NAME          | NO. | DOWN               | 1/0 ( /     | DESCRIPTION   |
| BOOT1         | 10  | -                  | Ι           | The capacitor on these pins acts as the voltage supply for the high-side MOSFET gate-drive circuitry.               |
| BOOT2         | 29  | -                  | I           | The capacitor on these pins acts as the voltage supply for the high-side MOSFET gate drive circuitry.               |
| BOOT3         | 42  | -                  | Ι           | The capacitor on these pins act as the voltage supply for the BUCK3 high-side MOSFET gate drive circuitry.          |
| COMP1         | 18  | -                  | 0           | Error amplifier output for the switching controller. External compensation network is connected to this node.       |
| COMP2         | 34  | -                  | Ι           | Compensation selection for the BUCK2 switching converter  |
| COMP3         | 37  | -                  | Ι           | Compensation selection for the BUCK3 switching converter.   |
| COMP5         | 20  | -                  | 0           | Error amplifier output for the boost switching controller. External compensation network is connected to this node. |
| CSN           | 44  | pull up            | Ι           | SPI – Chip select   |
| DVDD          | 55  | -                  | 0           | Internal DVDD output for decoupling   |
| EXTSUP        | 8   | -                  | Ι           | Optional LV input for gate driver supply  |
| GL            | 13  | -                  | 0           | Gate driver – low-side FET  |
| GND           | 56  | -                  | 0           | Analog GND, digital GND and substrate connection  |
| GPFET         | 3   | -                  | 0           | Gate driver external protection PMOS FET.   |
| GU            | 11  | -                  | 0           | Gate driver – high-side FET   |
| HSCTRL        | 5   | -                  | 0           | High-side gate driver output  |
| HSPWM         | 49  | pull down          | Ι           | High side and LED PWM input   |
| HSSENSE       | 6   | -                  | Ι           | Sense input high side and LED   |
| IRQ           | 28  | -                  | OD          | Low battery interrupt output in operating mode  |
| LDO_OUT       | 51  | -                  | 0           | Linear regulated output (connect a low ESR ceramic output capacitor to this terminal)                               |
| PGND1         | 14  | -                  | 0           | Ground for low-side FET driver  |

(1) Description of pin type: I = Input; O = Output; OD = Open-drain output



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# **PIN FUNCTIONS (continued)**

| PIN     |     | PULL UP / | ue (1)             | DESCRIPTION   |  |  |  |  |  |  |
|---------|-----|-----------|--------------------|---|--|--|--|--|--|--|
| NAME    | NO. | DOWN      | I/O <sup>(1)</sup> | DESCRIPTION   |  |  |  |  |  |  |
| PGND2   | 32  | -         | 0                  | Power ground of synchronous converter BUCK2   |  |  |  |  |  |  |
| PGND3   | 39  | -         | 0                  | Power ground of synchronous converter BUCK3   |  |  |  |  |  |  |
| PGND5   | 22  | -         | 0                  | Power ground boost converter  |  |  |  |  |  |  |
| PH1     | 12  | -         | 0                  | Switching node - BUCK1 (floating ground for high-side FET driver)   |  |  |  |  |  |  |
| PH2     | 31  | -         | 0                  | Switching node BUCK2  |  |  |  |  |  |  |
| PH3     | 40  | -         | 0                  | Switching node BUCK3  |  |  |  |  |  |  |
| PH5     | 23  | -         | 0                  | Switching node boost  |  |  |  |  |  |  |
| PRESN   | 26  | -         | OD                 | Peripherals reset   |  |  |  |  |  |  |
| RESN    | 27  | -         | OD                 | System reset  |  |  |  |  |  |  |
| S1      | 15  | -         | I                  | Differential current sense inputs for BUCK1, S2 pull-down only active in RAMP and ACTIVE state  |  |  |  |  |  |  |
| S2      | 16  | pull down | I                  |   |  |  |  |  |  |  |
| SCK     | 46  | pull down | I                  | SPI – Clock   |  |  |  |  |  |  |
| SDI     | 45  | pull down | I                  | SPI – Master out, slave in  |  |  |  |  |  |  |
| SDO     | 47  | -         | 0                  | SPI – Master in, slave out - push-pull output supplied by VIO   |  |  |  |  |  |  |
| VBOOST  | 24  | -         | I                  | Booster output voltage  |  |  |  |  |  |  |
| VIN     | 2   | -         | I                  | Unprotected supply input for the base functionality and band gap 1. Supplied blocks are: RESET, WD, wake, SPI, temp sensing, voltage monitoring and the logic block.  |  |  |  |  |  |  |
| VINPROT | 4   | -         | I                  | Main input supply pin (gate drivers and bandgap2)   |  |  |  |  |  |  |
| VIO     | 48  | -         | I                  | Supply input for the digital interface to the MCU. Voltage on this input is monitored. If VIO falls below UV threshold a reset is generated and the part enters error mode.   |  |  |  |  |  |  |
| VMON1   | 17  | -         | I                  | Input pin for the independent voltage monitor at BUCK1  |  |  |  |  |  |  |
| VMON2   | 33  | -         | I                  | Input pin for the independent voltage monitor at BUCK2  |  |  |  |  |  |  |
| VMON3   | 38  | -         | I                  | Input pin for the independent voltage monitor at BUCK3  |  |  |  |  |  |  |
| VREF    | 53  | -         | 0                  | Accurate reference voltage output for peripherals on the system (for example, ADC)  |  |  |  |  |  |  |
| VREG    | 9   | -         | 0                  | Internal regulator for gate driver supply (decoupling) and VREF   |  |  |  |  |  |  |
| VSENSE1 | 19  | -         | I                  | Input for externally sensed voltage of the output using a resistor divider network from their respective output line to ground.   |  |  |  |  |  |  |
| VSENSE2 | 35  | -         | I                  | Input for externally sensed voltage of the output using a resistor divider network from their respective output line to ground  |  |  |  |  |  |  |
| VSENSE3 | 36  | -         | I                  | Input for externally sensed voltage of the output using a resistor divider network from their respective output line to ground  |  |  |  |  |  |  |
| VSENSE4 | 52  | -         | I                  | Input for externally sensed voltage of the output using a resistor divider network from their respective output line to ground.   |  |  |  |  |  |  |
| VSENSE5 | 21  | -         | I                  | Input for externally sensed voltage of the boost output using a resistor divider network from their respective output line to ground.   |  |  |  |  |  |  |
| VSSENSE | 1   | -         | I                  | Input to monitor the battery line for undervoltage conditions. UV is indicated by the IRQ pin.  |  |  |  |  |  |  |
| VSUP2   | 30  | -         | I                  | Input voltage supply for switch mode regulator BUCK2  |  |  |  |  |  |  |
| VSUP3   | 41  | -         | I                  | Input voltage supply for switch mode regulator BUCK3  |  |  |  |  |  |  |
| VSUP4   | 50  | -         | I                  | Input voltage supply for linear regulator LDO   |  |  |  |  |  |  |
| VT      | 54  | -         | I                  | Input pin for the comparator with shutdown functionality. This input can be used to sense an external NTC resistor to shutdown the IC in case the ambient temperature is too high or too low. Tie to GND if not in use. |  |  |  |  |  |  |
| VT_REF  | 25  | -         | 0                  | Shutdown comparator reference output. Internally connected to DVDD, current-limited. When not in use can be connected to DVDD or left open.   |  |  |  |  |  |  |
| WAKE    | 7   | pull down | I                  | Wake up input   |  |  |  |  |  |  |
| WD      | 43  | pull down | I                  | Watchdog input pin. WD is the trigger input coming from the MCU.  |  |  |  |  |  |  |

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Figure 2. Detailed Block Diagram



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## **TYPICAL CHARACTERISTICS**

All parameters are measured on a TI EVM, unless otherwise specified.

## **BUCK 1 Characteristics**







805

804

803

802

<u>ک</u> 801

NSENSE2 (1 800 799

798

797

796

795

10

9

8

7

3

2

1

0

VSENSE2 (mV)

3

I\_VSUP2 (mA) 6 5 4



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**TYPICAL CHARACTERISTICS (continued)** OPEN-LOAD LINE REGULATION BUCK3 = 1.2 V EXTSUP PIN OPEN OPEN-LOAD LINE REGULATION BUCK2 = 3.3 V EXTSUP PIN OPEN 805 25°C 25°C 804 -40°C -40°C 803 140°C 140°C 802 **NSENSE3 (mV)** 800 799 798 797 796 795 2 4 6 8 10 12 2 4 6 8 10 12 VSUP3 (V) VSUP2 (V) Figure 6. Figure 7. OPEN-LOAD SUPPLY CURRENT BUCK2 = 3.3 V EXTSUP PIN OPEN OPEN-LOAD SUPPLY CURRENT BUCK3 = 1.2 V EXTSUP PIN OPEN 6 5.5 5 4.5 4 (WW) 3.5 3 2.5 2.5 2 25°C 25°C 15 -40°C -40°C 1 125°C 0.5 140°C 0 5 9 11 2 12 7 4 6 8 10 VSUP3 (V) VSUP2 (V) Figure 8. Figure 9. Buck2 = 3.3-V VSENSE2 Buck3 = 1.2-V VSENSE3 vs TEMPERATURE EXTSUP PIN OPEn vs TEMPERATURE EXTSUP PIN OPEN 801 802 801.5 800.5 801 800 VSENSE3 (mV) 800.5 799.5 800 799 799.5 798.5 VSUP2 = 3.8 V, NO LOAD 799 VSUP3 = 3.8 V, NO LOAD 798 50 -30 -10 10 30 50 70 90 110 130 150 798.5 -50 -30 -10 110 130 30 50 90 Temperature (°Celcius) Temperature (°Celcius) Figure 10. Figure 11.

150



**BOOST Characteristics** 

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## TYPICAL CHARACTERISTICS (continued)





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## **TYPICAL CHARACTERISTICS (continued)**

## **LDO Noise Characteristics**

 $(2 \times 3.3 \text{-}\mu\text{F} \text{ output capacitance, LDO output} = 2.5 \text{ V}, \text{ VSUP4} = 3.8 \text{ V})$ 





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## DETAILED DESCRIPTION

## **BUCK CONTROLLER (BUCK1)**

#### **Operating Modes**

| Mode of Operation | Description   |
|-------------------|---|
|                   | Constant frequency current mode<br>Continuous or discontinuous mode |

#### Normal Mode PWM Operation

The main buck controller operates using constant frequency peak current mode control. The output voltage is programmable with external resistors.

The switching frequency is set to a fixed value of  $f_{SWBUCK1}$ . Peak current-mode control regulates the peak current through the inductor such that the output voltage VBUCK1 is maintained to its set value. Current mode control allows superior line-transient response. The error between the feedback voltage VSENSE1 and the internal reference produces an error signal at the output of the error amplifier (COMP1) which serves as target for the peak inductor current. At S1–S2, the current through the inductor is sensed as a differential voltage and compared with this target during each cycle. A fall or rise in load current produces a rise or fall in voltage at VSENSE1, which causes COMP1 to rise or fall respectively, thus increasing or decreasing the current through the inductor until the average current matches the load. In this way the output voltage VBUCK1 is maintained in regulation.



Figure 16. Detailed Block Diagram of Buck 1 Controller

of 98.75%.

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The high-side N-channel MOSFET is turned on at the beginning of each clock cycle and kept on until the inductor current reaches its peak value as set by the voltage loop. Once the high external FET is turned OFF, and after a small delay (shoot-through delay), the lower N-channel MOSFET is turned on until the start of the next clock cycle. In dropout operation the high-side MOSFET stays on 100%. In every fourth period the duty cycle is limited to 95% in order to charge the bootstrap capacitor at BOOT1. This allows a maximum duty cycle

The maximum value of COMP1 is clamped so that the maximum current through the inductor is limited to a specified value. The BUCK1 controller output voltage is monitored by a central independent voltage-monitoring circuit, which has an independent voltage-monitoring bandgap reference for safety reasons. In addition, BUCK1 is thermally protected with a dedicated temperature sensor.

## Output Inductor, Sense Resistor and Capacitor selection for the BUCK1 Controller

An external resistor senses the current through the inductor. The current sense resistor nodes (S1 and S2) are fed into an internal differential amplifier which supports the range of VBUCK1 voltages. The sense resistor Rs must be chosen so that the maximum forward peak current in the inductor generates a voltage of 75 mV across the sense pins. This specified typical value is for low duty cycles only. At typical duty-cycle conditions around 28% (assuming 3.3-V output and 12-V input), 50 mV is a more reasonable value, considering tolerances and mismatches. The typical characteristics (see Figure 3) provide a guide for using the correct current-limit sense voltage.

$$Rs = \frac{50 \text{ mV}}{I_{\text{max_peak}}}$$
(1)

Optimal slope compensation which is adaptive to changes in input voltage and duty cycle allows stable operation at all conditions. In order to specify optimal performance of this circuit, the following condition must be satisfied in the choice of inductor and sense resistor:

$$L=410\times R_s$$

where

 $L = inductor in \mu H$  $R_{s}$  = sense resistor in  $\Omega$ 

The current sense pins S1 and S2 are high impedance pins with low leakage across the entire VBUCK1 range. This allows DCR current sensing (see Figure 16) using the DC resistance of the inductor for better efficiency.

For selecting the output capacitance and its ESR resistance, the following set of equations can be used:

$$\begin{split} C_{out} &> \frac{2 \times \Delta I_{out}}{fsw \times \Delta V_{out}} \\ C_{out} &> \frac{1}{8 \times fsw} \times \frac{I_{L - ripple}}{V_{o\_ripple}} \\ R_{ESR} &< \frac{V_{o\_ripple}}{I} \end{split}$$

I<sub>L -ripple</sub>

where

- $f_{sw}$  is the 440-kHz switching frequency
- $\Delta I_{out}$  is the worst-case load step from the application
- $\Delta V_{out}$  is the allowed voltage step on the output
- Vo ripple is the allowed output voltage ripple
- $I_{L_{ripple}}$  is the ripple current in the coil

(3)

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(1)

(2)



(4)

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#### **Compensation of the Buck Controller**

The main buck controller requires external type 2 compensation on pin COMP1 for normal mode operation. The components can be calculated as follows.

- 1. Choose bandwidth F<sub>BW</sub> to be between f<sub>SWBUCK1</sub> / 6 (faster response) and f<sub>SWBUCK1</sub> / 10 (more conservative)
- 2. Choose R<sub>1</sub> (see Figure 16)

$$R_{1} = \frac{2\pi \times F_{BW} \times V_{OUT1} \times C_{OUT1}}{gm \times K_{CFB} \times V_{refBUCK}}$$

where

- C<sub>OUT1</sub> is the load capacitance of BUCK1
- gm is the error amplifier transconductance
- K<sub>CFB</sub> = 0.125 / R<sub>s</sub>
- V<sub>refBUCK</sub> is the internal reference voltage
- 3. Choose  $C_1$  (in series with  $R_1$ , see Figure 16) to set the zero frequency close to  $F_{BW}$  / 10

$$C_1 = \frac{10}{2\pi \times R_1 \times F_{BW}}$$
(5)

4. Choose  $C_2$  (parallel with  $R_1, C_1$ , see Figure 16) to set the second pole below  $f_{SWBUCK1} / 2$ 

$$C_2 = \frac{1}{2\pi \times R_1 \times F_{BW} \times 3}$$
(6)

For example:

 $f_{SWBUCK1} = 490 \text{ kHz}, V_{refBUCK} = 0.8 \text{ V}, F_{BW} = 60 \text{ kHz}$ 

 $V_{OUT1}$  = 3.3 V,  $C_{OUT1}$  = 100 µF,  $R_s$  = 20 m $\Omega$ 

Chosen values:  $R_1 = 24 \text{ k}\Omega$ ,  $C_1 = 1.2 \text{ nF}$ ,  $C_2 = 33 \text{ pF}$ 

Resulting in F<sub>BW</sub>: 58 kHz

Resulting in zero frequency: 5.5 kHz

Resulting in second pole frequency: 201 kHz

Stability and load step response must be verified in measurements to fine tune the values of the compensation components.

## Synchronous Buck Converters BUCK2 and BUCK3

Both regulators are synchronous converters operating with a fixed switching frequency  $f_{sw}$  = 2.45 MHz. For each buck converter, the output voltage is programmable with external resistors. The synchronous operation mode improves the overall efficiency. BUCK3 switches in phase with BUCK1, and BUCK2 switches at a 216° shift to BUCK3 to minimize input current ripple.

Each buck converter can provide a maximum current of 2 A and is protected against short circuits to ground. In case of a short circuit to ground, the integrated cycle-by-cycle current limit turns off the high-side FET when its current reaches  $I_{HS-Limit}$  and the low-side FET is turned on until the end of the given cycle. When the current limit is reached in the beginning of the cycle for five consecutive cycles, the pulse-width modulation (PWM) is forced low for sixteen cycles to prevent uncontrolled current build-up. In case the low-side current limit of  $I_{LS-Limit}$  is reached, for example, due an output short to VSUP2/3, the low-side FET is turned off until the end of the cycle. If this is detected shortly after the high-low PWM transition (immediately after the low-side overcurrent comparator blanking time), both FETs are turned off for sixteen cycles.

The output voltages of BUCK2/3 regulators are monitored by a central independent voltage-monitoring circuit, which has an independent voltage-monitoring bandgap reference for safety reasons. In addition BUCK2 and BUCK3 are thermally protected with a dedicated temperature sensor.

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# Output Inductor Selection for the BUCK2 and BUCK3 Converter

The inductor value L depends on the allowed ripple current  $\Delta I_{L_{PP}}$  in the coil at chosen input voltage  $V_{IN}$  and output voltage  $V_{OUT}$ , and given switching frequency  $f_{sw}$ :

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\Delta I_{L_{PP}} \times V_{IN} \times f_{sw}}$$

For example:

 $V_{IN}$  = 3.3 V (from BUCK1)  $V_{OUT}$  = 1.2 V  $\Delta I_{L_{PP}}$  = 300 mA  $f_{sw}$  = 2.45 MHz → L ≈ 1 µH

## Compensation of the BUCK2 and BUCK3 Converters

The regulators operate in forced continuous mode, and have internal frequency compensation. The frequency response can be adjusted to the selected LC filter by setting the COMP2/3 pin low, high or floating. After selecting the output inductor value as previously described, the output capacitor must be chosen so that the L  $\times$  C<sub>OUT</sub>  $\times$  V<sub>BUCK2/3</sub> product equals one of the three values, as listed in Table 1.

#### **Table 1. Compensation Settings**

| COMP 2/3 | L × C <sub>OUT</sub> × V <sub>BUCK2/3</sub> | Example Components      |
|----------|---|-------------------------|
| = 0 V    | 80 μF × μH × V                              | 30 μF × 2.2 μH × 1.2 V  |
| = OPEN   | 160 μF × μH × V                             | 50 μF × 1.8 μH × 1.8 V  |
| = VREG   | 320 μ <b>F ×</b> μ <b>H ×</b> V             | 150 μF × 2.2 μH × 1.2 V |

Larger output capacitors can be used if a feed-forward capacitor is placed across the feedback divider. This works effectively for output voltages > 2 V. With an RC product greater than 10  $\mu$ s, V<sub>BUCK2/3</sub> can be assumed as 0.8 V, thus allowing an output capacitor increase by a factor equal to the ratio of the output voltage to 0.8 V.

## **BOOST Converter**

The BOOST converter is an asynchronous converter operating with a fixed switching frequency  $f_{sw}$  = 2.45 MHz. It switches in phase with BUCK1. At low load, the boost regulator switches to pulse skipping.

The output voltage is programmable with external resistors.

The internal low-side switch can handle maximum 1-A current, and is protected with a current limit. In case of an overcurrent, the integrated cycle-by-cycle current limit turns off the low-side FET when its current reaches  $I_{CLBOOST}$  until the end of the given cycle. When the current limit is reached in the beginning of the cycle for five consecutive cycles, the PWM is forced low for sixteen cycles to prevent uncontrolled current build-up.

The BOOST converter output voltage is monitored by a central independent voltage-monitoring circuit, which has an independent voltage-monitoring bandgap reference for safety reasons. If the  $V_{MONTH_L} > V_{SENSE5}$  or  $V_{SENSE5} > V_{MONTH_H}$ , the output is switched off and the BOOST\_FAIL bit in the SPI PWR\_STAT register is set. The BOOST can be reactivated by setting BOOST\_EN bit in the PWR\_CONFIG register.

In addition, the BOOST converter is thermally protected with a dedicated temperature sensor. If  $T_J > T_{OTTH}$ , the BOOST converter is switched off and bit OT\_BOOST in PWR\_STAT register is set. Reactivation of the booster is only possible if the OT\_BOOST bit is 0, and the booster enable bit in the PWR\_CONFIG register is set to 1.

(7)



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(10)

(12)

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#### **Output Inductor and Capacitor Selection for the BOOST Converter**

The inductor value L depends on the allowed ripple current  $\Delta I_{L_{PP}}$  in the coil at chosen input voltage  $V_{IN}$  and output voltage  $V_{OUT}$ , and given switching frequency  $f_{sw}$ :

$$L = \frac{V_{IN} \times (V_{OUT} - V_{IN})}{\Delta I_{L_{PP}} \times V_{OUT} \times f_{sw}}$$
(8)

For example:

 $V_{IN}$  = 3.3 V (from BUCK1)  $V_{OUT}$  = 5 V  $\Delta I_{LPP}$  = 300 mA (30% of 1-A peak current)  $f_{sw}$  = 2.45 MHz → L ≈ 1.5 µH

The capacitor value  $C_{OUT}$  has to be chosen such that the L-C double-pole frequency  $F_{LC}$  is in the range of 10 kHz–15 kHz. The  $F_{LC}$  is given by Equation 9:

$$F_{LC} = \frac{V_{IN}}{2 \times \pi \times V_{OUT} \times \sqrt{L \times C_{OUT}}}$$
(9)

The right half-plane zero  $F_{RHPZ}$ , as given in Equation 10, must be > 200 kHz:

$$F_{RHPZ} = \frac{V_{IN}^{2}}{L \times I_{OUT} \times V_{OUT}} > 200 \text{ kHz}$$

where

٠

IOUT represents the load current

If the condition  $F_{RHPZ}$  > 200 kHz is not satisfied, L and hence  $C_{OUT}$  have to be recalculated.

#### Compensation of the BOOST Converter

The BOOST converter requires an external R-C network for compensation (see Figure 2, COMP5). The components can be calculated using Equation 11 and Equation 12:

$$R = 120 \times V_{IN} \times \left(\frac{F_{BW}}{F_{LC}}\right)^{2}$$

$$C = \frac{1}{2 \times \pi \times R \times F_{LC}}$$
(11)

where

F<sub>BW</sub> represents the bandwidth of the regulation loop, and must be set to 30 kHz

• F<sub>LC</sub> represents the L-C double-pole frequency, as mentioned previously

For example:

$$\begin{split} V_{\text{IN}} &= 3.3 \text{ V} \text{ (from BUCK1)} \\ V_{\text{OUT}} &= 5 \text{ V} \\ L &= 3.3 \ \mu\text{H} \\ C &= 20 \ \mu\text{F} \\ &\rightarrow F_{\text{LC}} &= 12.9 \ \text{kHz} \\ F_{\text{BW}} &= 30 \ \text{kHz} \\ &\rightarrow R \approx 2.2 \ \text{k}\Omega \\ &\rightarrow C \approx 5.6 \ \text{nF} \end{split}$$

Stability and load step response must be verified in measurements to fine tune the values of the compensation components.



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## FREQUENCY-HOPPING SPREAD SPECTRUM

The TPS65311-Q1 features a frequency-hopping pseudo-random spectrum or triangular spreading architecture. The pseudo-random implementation uses a linear feedback shift register that changes the frequency of the internal oscillator based on a digital code. The shift register is designed in such a way that the frequency shifts only by one step at each cycle to avoid large jumps in the buck and boost switching frequencies. The triangular function uses an up-down counter. Whenever spread spectrum is enabled (SPI command), the internal oscillator frequency is varied from one BUCK1 cycle to the next within a band of 0.8 x  $f_{OSC}$  ...  $f_{OSC}$  from a total of 16 different frequencies. This means that BUCK3 and BOOST also step through 16 frequencies. The internal oscillator can also change its frequency during the period of BUCK2, yielding a total of 31 frequencies for BUCK2.

## Linear Regulator LDO

The LDO is a low drop out regulator with an adjustable output voltage through an external resistive divider network. The output has an internal current-limit protection in case of an output overload or short circuit to ground. In addition, the output is protected against overtemperature. If  $T_J > T_{OTTH}$ , the LDO is switched off and bit OT\_LDO in PWR\_STAT register is set. Reactivation of the LDO is only possible through the SPI by setting the LDO enable bit in the PWR\_CONFIG register to 1 if the OT\_LDO bit is 0.

The LDO output voltage is monitored by a central independent voltage-monitoring circuit, which has an independent voltage-monitoring bandgap reference for safety reasons. If the  $V_{MONTH_L} > V_{SENSE4}$  or  $V_{SENSE4} > V_{MONTH_H}$ , the output is switched off and the LDO\_FAIL bit in the SPI PWR\_STAT register is set. The LDO can be reactivated through the SPI by setting the LDO\_EN bit in the PWR\_CONFIG register. In case of overvoltage in VTCHECK and RAMP mode, the GPFET is turned off and the device changes to ERROR mode.

## Gate Driver Supply

The gate drivers of the BUCK1 controller, BUCK2 and BUCK3 converters and the BOOST converter are supplied from an internal linear regulator. The internal linear regulator output (5.8-V typical) is available at the VREG pin and must be decoupled using a typical 2.2- $\mu$ F ceramic capacitor. This pin has an internal current-limit protection and must not be used to power any other circuits.

The VREG linear regulator is powered from VINPROT by default when the EXTSUP voltage is lower than 4.6 V (typical).

If the VINPROT is expected to go to high levels, there can be excessive power dissipation in this regulator when using large external MOSFETs. In this case, it is advantageous to power this regulator from the EXTSUP pin, which can be connected to a supply lower than VINPROT but high enough to provide the gate drive. When EXTSUP is connected to a voltage greater than 4.6 V, the linear regulator automatically switches to EXTSUP as its input to provide this advantage. This automatic switch-over to EXTSUP can only happen once the TPS65311-Q1 device reaches ACTIVE mode. Efficiency improvements are possible when one of the switching regulator rails from the TPS65311-Q1, or any other voltage available in the system is used to power EXTSUP. The maximum voltage that must be applied to EXTSUP is 12 V.

## RESET

RESN and PRESN are open drain outputs which are active if one or more of the conditions listed in Table 2 are valid. RESN active (low) is extended for t<sub>RESNHOLD</sub> after a reset is triggered. RESN is the main processor reset and also asserts PRESN as a slave signal.

PRESN is latched and is released when window trigger mode of the watchdog is enabled (first rising edge at WD pin).

RESN and PRESN must keep the main processor and peripheral devices in a defined state during power up and power down in case of improper supply voltages or a critical failure condition. Therefore, for low supply voltages the topology of the reset outputs specify that RESN and PRESN are always held at a low level when RESN and PRESN are asserted, even if  $V_{IN}$  falls below  $V_{POR}$  or the device is in SHUTDOWN mode.



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| POR, Loss of LPM Clock, and Thermal Shutdown | The device reinitializes all registers with their default values. Error counter is cleared.   |
|--|---|
| Voltage Monitor BUCK 1-3                     | Input voltage at V <sub>MON1-3</sub> pin out-of-bounds:<br>V <sub>VMON1-3</sub> < V <sub>MONTH_L</sub> or V <sub>VMON1-3</sub> > V <sub>MONTH_H</sub> |
| Over Voltage LDO                             | V <sub>sense4</sub> > V <sub>MONTH_H</sub>  |
| Voltage Monitor VIO                          | Input voltage at VIO pin out-of-bounds: V <sub>VIO</sub> < V <sub>VIOMON TH</sub>   |
| Loss of GND                                  | Open at PGNDx or GND pin  |
| OT BUCK1-3, VREG                             | Overtemperature on BUCK1–3 or VREG  |
| WD_RESET                                     | Watchdog window violation   |

Any reset event (without POR, thermal shutdown, or loss of LPM clock) increments the error counter (EC) by one. After a reset is consecutively triggered  $N_{RES}$  times, the device transfers to the LPM0 state, and the EC is reset to 0. The counter is decremented by one if an SPI LPM0\_CMD is received. Alternatively, the device can be put in LOCK state once an SPI LOCK\_CMD is received. Once the device is locked, it cannot be activated again by a wake condition. The reset counter and lock function avoid cyclic start-up and shut-down of the device in case of a persistent fault condition. The reset counter content is cleared with a POR condition, a thermal shutdown or a loss of LPM clock. Once the device is locked, a voltage below  $V_{POR}$  at VIN pin or a thermal shutdown condition are the only ways to unlock the device.

## SOFT START

The output voltage slopes of BUCK, BOOST and LDO regulators are limited during ramp-up (defined by t<sub>STARTx</sub>). During this period the target output voltage slowly settles to its final value, starting from 0 V. In consequence, regulators that offer low-side transistors (BUCK1, BUCK2 and BUCK3) actively discharge their output rails to the momentary ramp-value if previously charged to a higher value.

## **Operating Modes**

## INIT

Coming from a power-on reset the device enters INIT mode. The configuration data from the EEPROM is loaded in this mode. If the checksum is valid and the internal VREG monitor is indicating an undervoltage condition (self-test VREG comparator), the device enters TESTSTART.



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## TESTSTART

TESTSTART mode is entered:

- After the INIT state (coming from power on)
- After detecting that VT > VT<sub>TH-H</sub>
- After ERROR mode and the fail condition is gone
- After a wake command in LPM0

In this mode the OV/UV comparators of BUCK1-3, BOOST, LDO and VIO are tested. The test is implemented in such a way that during this mode all comparators have to deliver a 1 (fail condition). If this is the case the device enters TESTSTOP mode.

If this is not the case, the device stays in TESTSTART. If the WAKE pin is low, the device enters LPM0 after  $t_{timeout}$ . If pin WAKE is high, the part stays in TESTSTART.

#### TESTSTOP

In this mode the OV/UV comparators are switched to normal operation. It is expected that only the UV comparators give a fail signal. In case there is an OV condition on any rail or one of the rails has an overtemperature the device stays in TESTSTOP. If the WAKE pin is low the device enters LPM0 mode after  $t_{timeout}$ . If the WAKE pin is high, the part stays in TESTSTOP. If there is no overvoltage and overtemperature detected, the part enters VTCHECK mode.

#### VTCHECK

VTCHECK mode is used to:

- 1. Switch on external GPFET in case VIN <  $V_{OVTH L}$
- 2. Turn on VREG regulator and VT\_REF
- 3. Check if voltage on pin VT < VT<sub>TH-L</sub>
- 4. Check if SMPS clock is running correctly
- 5. Check if VREG, VT\_REF exceed the minimum voltage

If all checks are valid the part enters the RAMP state. In case the device is indicating a malfunction and the WAKE pin is low, the device enters LPM0 after t<sub>timeout</sub> to reduce current consumption.

In case the voltage monitors detect an overvoltage condition on BUCK1-3/LDO, a loss of GND or an overtemperature condition on BUCK1-3 / VREG the device enters ERROR mode and the error counter is increased.

#### RAMP

In this mode the device runs through the power-up sequencing of the SMPS rails (see Figure 18).

#### Power-up Sequencing

After the power-up sequence (described in Figure 18), all blocks are fully functional. BUCK1 starts first. After  $t_{SEQ2}$  elapses and BUCK1 is above the undervoltage threshold, BUCK2 and BOOST start. BUCK3 and VREF start one  $t_{SEQ1}$  after BUCK2. After the release of RESN pin, the  $\mu$ C can enable the LDO per SPI by setting bit 4 LDO\_EN in PWR\_CONFIG register to 1 (per default, this LDO\_EN is set to 0 after each reset to the  $\mu$ C).

In case any of the following conditions occurduring power-up sequencing, the device enters ERROR mode and the error counter (EC) is increased:

- Overtemperature on BUCK1-3 or VREG
- Overvoltage on BUCK1-3 or LDO
- Overcurrent on BUCK1
- SMPS clock fail
- VT\_REF/VREG undervoltage
- Loss of GND

In case VT >  $VT_{TH-H}$ , the device transitions to TESTSTART.



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After the power-up sequence is completed (except LDO) without detecting an error condition, the device enters ACTIVE mode.



## Power-down Sequencing

There is no dedicated power-down sequencing. All rails are switched off at the same time. The external FETs of BUCK1 are switched off and the outputs of BUCK2/3/BOOST (PHx) and the LDO are switched in a high-impedance state.

## ACTIVE

This is the normal operating mode of the device. Transitions to other modes:

#### $\rightarrow$ ERROR

The device is forced to go to ERROR in case of:

- Any RESET event (without watchdog reset)
- VREG/VREF/VT\_REF below undervoltage threshold
- SMPS clock fail

During the transition to ERROR mode the EC is incremented.

#### $\rightarrow$ LOCKED

In case a dedicated SPI command (SPI\_LOCK\_CMD) is issued.

#### $\rightarrow$ TESTSTART

The device moves to TESTSTART after detecting that  $VT < VT_{TH-L}$ .

#### $\rightarrow$ LPM0

The device can be forced to enter LPM0 with a SPI LPM0 command. During this transition the EC is decremented.

If the EC reaches the  $N_{RES}$  value, the device transitions to LPM0 mode and EC is cleared. Depending on the state of the WAKE pin, the device remains in LMP0 (WAKE pin low) or restart to TESTSTART (WAKE pin high). To indicate the device entered LPM0 after EC reached  $N_{RES}$  value, a status bit EC\_OF (error counter overflow, SYS\_STAT bit 3) is set. The EC\_OF bit is cleared on read access to the SYS\_STAT register.

A watchdog reset in ACTIVE mode only increases the EC, but it does not change the device mode.

## ERROR

In this mode all power stages and the GPFET are switched off. The devices leave ERROR mode and enter TESTSTART if:

- All rails indicate an undervoltage condition
- No GND loss is detected
- No overtemperature condition is detected

When the EC reaches the N<sub>RES</sub> value, the device transitions to LPM0 and the EC is cleared. To indicate the device entered LPM0 after EC reached N<sub>RES</sub>, a status bit EC\_OF (error counter overflow, SYS\_STAT bit 3) is set. The EC\_OF bit is cleared on read access to the SYS\_STAT register.

## LOCKED

Entering this mode disables the device. The only way to leave this mode is through a power-on reset, thermal shutdown, or the loss of an LPM clock.

#### LPM0

Low-power mode 0 is used to reduce the quiescent current of the system when no functionality is needed. In this mode the GPFET and all power rails except for DVDD are switched off.

In case a voltage >  $V_{WAKE_ON}$  longer than  $t_{WAKE}$  is detected on the WAKE pin, the part switches to TESTSTART mode.



#### SHUTDOWN

The device enters and stays in this mode, as long as  $T_J > T_{SDTH} - T_{SDHY}$  or  $V_{IN} < V_{POR}$  or DVDD under or overvoltage, or loss of low power clock is detected. Leaving this mode and entering INIT mode generates an internal POR.

#### Power-on Reset Flag

The POR flag in the SYS\_STAT SPI register is set:

- When V<sub>IN</sub> is below the V<sub>POR</sub> threshold
- System is in thermal shutdown
- Over or undervoltage on DVDD
- Loss of low power clock

#### WAKE PIN

Only when the device is in LPM0 mode, it can be activated by a positive voltage on the WAKE pin with a minimum pulse width  $t_{WAKE}$ . A valid wake condition is latched. Normal deactivation of the device can only occur through the SPI Interface by sending an SPI command to enter LMP0. Once in LMP0, the device stays in LPM0 when the WAKE pin is low, or restarts to TESTSTART when the WAKE pin is high.

The WAKE pin has an internal pulldown resistance R<sub>PD-WAKE</sub>, and the voltage on the pin is not allowed to exceed 60 V. A higher voltage compliance level in the application can be achieved by applying an external series resistor between the WAKE pin and the external wake-up signal.

The device cannot be re-enabled by toggling the WAKE pin when the device is in LOCKED state (by SPI command).

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**INSTRUMENTS** 

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The IRQ pin has two different functions. In OPERATING mode, the pin is forced low when the voltage on the battery line is below the  $V_{SSENSETHx}$  threshold. The IRQ pin is low as long as PRESN is low. If PRESN goes high and the battery line is already below the  $V_{SSENSETHx}$  threshold, the IRQ pin is forced high for  $t_{VSSENSE_{BLK}}$ .

## **VBAT Undervoltage Warning**

- Low battery condition on VSSENSE asserts IRQ output (interrupt for μC, open drain output)
- Sense input can be directly connected to VBAT through the resistor
- Detection threshold for undervoltage warning can be selected through the SPI.
- An integrated filter time avoids false reaction due to spikes on the VBAT line.

## **VIN Over or Undervoltage Protection**

- Undervoltage is monitored on the V<sub>IN</sub> line, for POR generation.
- Two V<sub>IN</sub> overvoltage shutdown thresholds (V<sub>OVTH</sub>) can be selected through the SPI. After POR, the lower threshold is enabled.
- During LPM0, only the POR condition is monitored.
- An integrated filter time avoids false reaction due to spikes on the V<sub>IN</sub> line.
- In case of overvoltage, the external PMOS is switched off to protect the device. The BUCK1 controller is not switched off and it continues to run until the undervoltage on VREG or BUCK1 output is detected.



Figure 20. Over or Undervoltage Detection Circuitry

## **External Protection**

The external PMOS switch is disabled if:

- The device detects V<sub>IN</sub> overvoltage
- The device is in ERROR, LOCKED, POR, INIT, TESTSTART, TESTSTOP or LPM0 mode

**NOTE** Depending on the application, the external PMOS may be omitted as long as VBAT < 40 V

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Figure 21. PMOS Control Circuitry

## Overtemperature Detection and Shutdown

There are two levels of thermal protection for the device.

Overtemperature is monitored locally on each regulator.

**OT for BUCK1-3**: If a thermal monitor on the buck rails reaches a threshold higher than  $T_{OTTH}$ , the device enters ERROR mode. Leaving ERROR mode is only possible if the temperature is below  $T_{OTTH}$ - $T_{OTHY}$ .

**OT for BOOST/LDO**: If the temperature monitor of the boost or the LDO reaches the  $T_{OTTH}$  threshold, the corresponding regulator is switched off.

**Overtemperature Shutdown**: is monitored on a central die position. In case the  $T_{SDTH}$  is reached, the device enters shutdown mode. It leaves shutdown when the TSD sensor is below  $T_{SDTH} - T_{SDHY}$ . This event internally generates a POR.

## Independent Voltage Monitoring

The device contains independent voltage-monitoring circuits for BUCK1–3, LDO, VIO and BOOST. The reference voltage for the voltage monitoring unit is derived from an independent bandgap. BUCKs 1–3 use separate input pins for monitoring. The monitoring circuit is implemented as a window comparator with an upper and lower threshold.

If there is a violation of the upper (only LDO [RAMP, VTCHECK], or BUCK1–3) or lower threshold (only BUCK1–3, or VIO), the device enters ERROR mode, RESN and PRESN are asserted low, the external PMOS (main system switch) is switched off, and the EC is incremented.

In TESTSTART mode, a self-test of the independent voltage monitors is performed.

In case any of the supply rails for BUCK2/3, LDO or BOOST are not used in the application, the respective VMON2/3 or VSENSE4/5 pin of the unused supply must be connected to VMON1. Alternatively, the VSENSE4 pin can also be connected directly to ground in case the LDO is not used.

## **GND Loss Detection**

All power grounds PGNDx are monitored. If the voltage difference to GND exceeds  $V_{GLTH-low}$  or  $V_{GLTH-high}$ , the device enters ERROR mode. RESN and PRESN are asserted low, the external PMOS (main system switch) is switched off, and the EC is incremented.

## Reference Voltage

The device includes a precise voltage reference output to supply a system ADC. If this reference voltage is used in the application, a decoupling capacitor between 0.6 and 5  $\mu$ F must be used. If this reference voltage is not used in the application, this decoupling capacitor can be left out. The VREF output is enabled in RAMP state. The output is protected against a short to GND.



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#### **Shutdown Comparator**

An auxiliary, short circuit protected output supplied from DVDD is provided at the VT\_REF pin. It is used as a reference for an external resistive divider to the VT pin. In case a voltage > VTTH is detected on the VT pin, the main switch (external PMOS driven by GPFET) is switched off. This functionality can be used to monitor over and under temperature (using a NTC resistor) to avoid operation below or above device specifications.

If the voltage at VT\_REF falls below  $V_{VT_{REF} SH}$  while the shutdown comparator is enabled, an ERROR transition occurs. The shutdown comparator is enabled in VTCHECK state, and can be turned off by SPI. Disabling the comparator saves power by also disabling the VT\_REF output.

#### LED and High-Side Switch Control

This module controls an external PMOS in current-limited high-side switch.

The current levels can be adjusted with an external sense resistor. Enable and disable is done with the HS\_EN bit. The switch is controlled by the HSPWM input pin. Driving HSPWM high turns on the external FET.

The device offers an open load diagnostic indicated by the HS\_OL flag in the SPI register PWR\_STAT. Open load is also indicated in case the voltage on VINPROT–VSSENSE does not drop below the threshold when PWM is low (self-test).

A counter monitors the overcurrent condition to detect the risk of overheating. While HSPWM = high and HS\_EN = high the counter is incremented during overcurrent conditions, and decremented if the current is below the overcurrent threshold at a sampling interval of  $t_{S HS}$  (shown in Figure 23). When reaching a net current limit time of  $t_{HSS CL}$ , the driver is turned off and the HS\_EN bit is cleared. This feature can be disabled by SPI bit HS\_CLDIS. When HS\_EN is cleared, the counter is reset.



Figure 22. High-Side Control Circuit



#### NOTE

In case the LED or High-Side Switch Control is not used in the application, HSSENSE must be connected to VINPROT.

## Window Watchdog

#### WD in Operating Mode

The WD is used to detect a malfunction of the MCU and DSP. Description:

- Timeout trigger mode with long timing starts on the rising edge at RESN
- Window trigger mode with fixed timing after the first and each subsequent rising edge at the WD pin
- Watchdog is triggered by rising edge at the WD pin

A watchdog reset happens by:

- A trigger pulse outside the WD trigger open window
- No trigger pulse during window time

After the RESN pin is released (rising edge) the DSP and MCU must trigger the WD by a rising edge on the WD pin within a fixed time t<sub>timeout</sub>. With this first trigger, the window watchdog functionality is released.



## Figure 24. WD Window Description



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#### **Timeout in Start-up Modes**

A timer is used to limit the time during which the device can stay in each of the start-up modes: TESTSTART, TESTSTOP, VTCHECK and RAMP. If the device enters one of these start-up modes and  $V_{IN}$  or VT is not in a proper range, the part enters LPM0 after  $t_{timeout}$  is elapsed and the WAKE pin is low.

#### SPI

The SPI provides a communication channel between the TPS65311-Q1 and a controller. The TPS65311-Q1 is always the slave. The controller is always the master. The SPI master selects the TPS65311-Q1 by setting CSN (chip select) to low. SDI (slave in) is the data input, SDO (slave out) is the data output, and SCK (serial clock input) is the SPI clock provided by the master. If chip select is not active (high), the data output SDO is high impedance. Each communication consist of 16 bits.

1 bit parity (odd) (parity is built over all bits including: R/W, CMD\_ID[5:0], DATA[7:0])

1 bit R/W; read = 0 and write = 1

6 bits CMD identifier

8 bits data

| Bit15  | Bit14 | Bit13   | Bit12   | Bit11   | Bit10   | Bit9    | Bit8    | Bit7  | Bit6  | Bit5  | Bit4  | Bit3  | Bit2  | Bit1  | Bit0  |
|--------|-------|---------|---------|---------|---------|---------|---------|-------|-------|-------|-------|-------|-------|-------|-------|
| Parity | R/W   | CMD_ID5 | CMD_ID4 | CMD_ID3 | CMD_ID2 | CMD_ID1 | CMD_ID0 | DATA7 | DATA6 | DATA5 | DATA4 | DATA3 | DATA2 | DATA1 | DATA0 |

#### Figure 25. SPI Bit-Frame

Each command is valid if:

- A valid CMD\_ID is sent
- The parity bit (odd) is correct
- Exactly 16 SPI clocks are counted between falling and rising edge of CSN

The response to each master command is given in the following SPI cycle. The response address is the CMD\_ID of the previous sent message and the corresponding data byte. The response data is latched with the previous cycle such that a response to a write command is the status of the register before the write access. (Same response as a read access.) The response to an invalid command is the original command with the correct parity bit. The response to an invalid number of SPI clock cycles is a SPI\_SCK\_FAIL communication (CMD\_ID = 0x03). Write access to a read-only register is not reported as an SPI error and is treated as a read access. The initial answer after the first SPI command sent is:  $CMD_ID[5:0] = 0x3F$  and Data[7:0] 0x5A.

#### FSI Bit

The slave transmits an FSI bit between the falling edge of CSN and the rising edge of SCK. If the SDO line is high during this time, a failure occurred in the system and the MCU must use the PWR\_STAT to get the root cause. A low level of SDO indicates normal operation of the device.

The FSI bit is set when:  $PWR\_STAT ! = 0x00$ , or  $(SYS\_STAT and 0x98) ! = 0x00$ , or  $SPI\_STAT ! = 0x00$ . The FSI is cleared when all status flags are cleared.

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## **Register Map**

| CMD_ID | Name         | Bit7      | Bit6      | Bit5     | Bit4        | Bit3        | Bit2       | Bit1          | Bit0        |  |  |
|--------|--------------|-----------|-----------|----------|-------------|-------------|------------|---------------|-------------|--|--|
| 0x00   | NOP          |           | 0x00      |          |             |             |            |               |             |  |  |
| 0x03   | SPI_SCK_FAIL | 1         | 0         | 0        | SCK_OF      | SCK[3]      | SCK[2]     | SCK[1]        | SCK[0]      |  |  |
| 0x11   | LPM0_CMD     |           |           |          |             | 0xAA        |            |               | L           |  |  |
| 0x12   | LOCK_CMD     |           |           |          |             | 0x55        |            |               |             |  |  |
| 0x21   | PWR_STAT     | BUCK_FAIL | VREG_FAIL | OT_BUCK  | OT_LDO      | OT_BOOST    | LDO_FAIL   | BOOST_FAIL    | HS_OL       |  |  |
| 0x22   | SYS_STAT     | WD        | POR       | TestMode | SMPCLK_FAIL | EC_OF       | EC2        | EC1           | EC0         |  |  |
| 0x23   | SPI_STAT     |           |           |          |             |             | CLOCK_FAIL | CMD_ID FAIL   | PARITY FAIL |  |  |
| 0x24   | COMP_STAT    |           |           |          |             | BUCK3-1     | BUCK3-0    | BUCK2-1       | BUCK2-0     |  |  |
| 0x29   | Serial Nr 1  |           |           |          |             | Bit [7:0]   |            |               | L           |  |  |
| 0x2A   | Serial Nr 2  |           |           |          |             | Bit [15:8]  |            |               |             |  |  |
| 0x2B   | Serial Nr 3  |           |           |          | I           | Bit [23:16] |            |               |             |  |  |
| 0x2C   | Serial Nr 4  |           |           |          | I           | Bit [31:24] |            |               |             |  |  |
| 0x2D   | Serial Nr 5  |           |           |          | I           | Bit [39:32] |            |               |             |  |  |
| 0x2E   | Serial Nr 6  |           |           |          | I           | Bit [47:40] |            |               |             |  |  |
| 0x2F   | DEV_REV      | Major3    | Major2    | Major1   | Major0      | Minor3      | Minor2     | Minor1        | Minor0      |  |  |
| 0x31   | PWR_CONFIG   |           | BUCK2_EN  | BUCK3_EN | LDO_EN      | BOOST_EN    | HS_EN      | GPFET_OV_HIGH | IRQ_THRES   |  |  |
| 0x32   | DEV_CONFIG   |           |           |          |             | HL_CLDIS    | VT_EN      | RSV           | RSV         |  |  |
| 0x33   | CLOCK_CONFIG | F_EN      | SS_EN     | SS_MODE  | F4          | F3          | F2         | F1            | F0          |  |  |

# **Register Description**

| NOP 0x00    |      |      |      |      |      |      |      |      |
|-------------|------|------|------|------|------|------|------|------|
|             | Bit7 | Bit6 | Bit5 | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
| After RESET | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |
| Read        | 0    | 0    | 0    | 0    | 0    | 0    | 0    | 0    |
| Write       | d.c. |

#### SPI\_SCK\_FAIL 0x03

|                        | Bit7 | Bit6 | Bit5 | Bit4   | Bit3   | Bit2   | Bit1   | Bit0   |
|------------------------|------|------|------|--------|--------|--------|--------|--------|
| Default after<br>RESET | 1    | 0    | 0    | 0      | 0      | 0      | 0      | 0      |
| Read                   | 1    | 0    | 0    | SCK_OF | SCK[3] | SCK[2] | SCK[1] | SCK[0] |
| Write                  | d.c. | d.c. | d.c. | d.c.   | d.c.   | d.c.   | d.c.   | d.c.   |

| Bit Name  | Bit No. |      | Description   |  |  |  |  |  |
|---|---------|------|---|--|--|--|--|--|
|   |         | Betw | veen a falling and a rising edge of CSN, the number of SCK was greater than 16. |  |  |  |  |  |
| SCK_OF  | 4       | 0:   |   |  |  |  |  |  |
|   |         | 1:   | Number of SCK cycles was > 16   |  |  |  |  |  |
| Comment: This flag is cleared after its content is transmitted to the master. |         |      |   |  |  |  |  |  |

| Bit Name   | Bit No. | Description  |  |  |  |  |
|--|---------|--|--|--|--|--|
| SCK[3:0]   | 3:0     | The number of rising edges on SCK between a falling and a rising edge of CSN minus 1. Saturates at 0xF if 16 or more edges are received. |  |  |  |  |
| Comments This flam is cleaned often its context is transmitted to the meeter |         |  |  |  |  |  |

Comment: This flag is cleared after its content is transmitted to the master.

| LPM0_CMD 0x11   |                 |                  |            |      |      |      |      |      |
|-----------------|-----------------|------------------|------------|------|------|------|------|------|
|                 | Bit7            | Bit6             | Bit5       | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
| After RESET     | 0               | 0                | 0          | 0    | 0    | 0    | 0    | 0    |
| Read            | 0               | 0                | 0          | 0    | 0    | 0    | 0    | 0    |
| Write           | OxAA            |                  |            |      |      |      |      |      |
| This command is | used to send th | he device into l | _PM0 mode. |      |      |      |      |      |
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# **TPS65311-Q1**

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| LOCK_CMD 0x12     |             |                  |                |                |                 |                    |          |      |  |
|-------------------|-------------|------------------|----------------|----------------|-----------------|--------------------|----------|------|--|
|                   | Bit7        | Bit6             | Bit5           | Bit4           | Bit3            | Bit2               | Bit1     | Bit0 |  |
| After RESET       | 0           | 0                | 0              | 0              | 0               | 0                  | 0        | 0    |  |
| Read              | 0           | 0                | 0              | 0              | 0               | 0                  | 0        | 0    |  |
| Write             | ite 0x55    |                  |                |                |                 |                    |          |      |  |
| Sending a lock co | mmand (0x55 | ) brings the dev | vice into LOCK | mode. Onlv a P | OR brinas the c | levice out of this | s state. |      |  |

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| PWR_STAT 0x21        |           |           |         |        |          |          |            |       |  |
|----------------------|-----------|-----------|---------|--------|----------|----------|------------|-------|--|
|                      | Bit7      | Bit6      | Bit5    | Bit4   | Bit3     | Bit2     | Bit1       | Bit0  |  |
| Default after<br>POR | 0         | 0         | 0       | 0      | 0        | 0        | 0          | 0     |  |
| Read                 | BUCK_FAIL | VREG_FAIL | OT_BUCK | OT_LDO | OT_BOOST | LDO_FAIL | BOOST_FAIL | HS_OL |  |
| Write                | d.c.      | d.c.      | d.c.    | d.c.   | d.c.     | d.c.     | d.c.       | d.c.  |  |

| Bit Name   | Bit No. |     | Description  |  |  |  |  |
|--|---------|-----|--|--|--|--|--|
|  |         | BUC | CK power fail flag   |  |  |  |  |
| BUCK_FAIL  | 7       | 0:  |  |  |  |  |  |
|  |         | 1:  | Power stages shutdown detected caused by OC BUCK1, UV, OV, loss of GND (BOOST + all bucks) |  |  |  |  |
| BUCK_FAIL flag is cleared in case the fail condition is not present anymore and the flag is transmitted to the master. |         |     |  |  |  |  |  |

| Bit Name   | Bit No. |    | Description                    |  |  |  |  |
|--|---------|----|--------------------------------|--|--|--|--|
|  |         |    | rnal voltage regulator too low |  |  |  |  |
| VREG_FAIL  | 6       | 0: |                                |  |  |  |  |
|  |         | 1: | VREG fail                      |  |  |  |  |
| VREG FAIL flag is cleared in case the fail condition is not present anymore and the flag is transmitted to the master. |         |    |                                |  |  |  |  |

| Bit Name  | Bit No.   |     | Description                                     |  |  |  |
|---|-----------|-----|---|--|--|--|
|   |           | BUC | CK1-3 overtemperature flag                      |  |  |  |
| OT_BUCK   | OT_BUCK 5 | 0:  |   |  |  |  |
|   |           | 1:  | IC power stages shutdown due to overtemperature |  |  |  |
| OT flag is cleared in case the fail condition is not present anymore and the flag is transmitted to the master. |           |     |   |  |  |  |

| Bit Name  | Bit No. |    | Description                         |  |  |  |  |  |
|---|---------|----|-------------------------------------|--|--|--|--|--|
|   |         |    | overtemperature flag                |  |  |  |  |  |
| OT_LDO  | 4       | 0: |                                     |  |  |  |  |  |
|   |         | 1: | LDO shutdown due to overtemperature |  |  |  |  |  |
| OT flag is cleared in case the fail condition is not present anymore and the flag is transmitted to the master. |         |    |                                     |  |  |  |  |  |

| Bit Name  | Bit No. |    | Description                           |  |  |  |  |
|---|---------|----|---------------------------------------|--|--|--|--|
|   |         |    | st overtemperature flag               |  |  |  |  |
| OT_BOOST  | 3       | 0: |                                       |  |  |  |  |
|   |         | 1: | BOOST shutdown due to overtemperature |  |  |  |  |
| OT flag is cleared in case the fail condition is not present anymore and the flag is transmitted to the master. |         |    |                                       |  |  |  |  |

| Bit Name   | Bit No. |    | Description               |  |  |  |  |
|--|---------|----|---------------------------|--|--|--|--|
|  |         |    | under or overvoltage flag |  |  |  |  |
| LDO_FAIL   | 2       | 0: |                           |  |  |  |  |
|  |         | 1: | LDO out of regulation     |  |  |  |  |
| LDO_FAIL flag is cleared if there is no undervoltage and no overvoltage and the flag is transmitted to the master. |         |    |                           |  |  |  |  |

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| Bit Name  | Bit No. |      | Description                                   |  |  |  |
|---|---------|------|---|--|--|--|
|   |         | Boos | ster under or overvoltage flag or loss of GND |  |  |  |
| BOOST_FAIL  | 1       | 0:   |   |  |  |  |
|   |         | 1:   | Booster out of regulation                     |  |  |  |
| BOOST_FAIL flag is cleared if there is no undervoltage and no overvoltage and the flag was transmitted to the master. |         |      |   |  |  |  |

| Bit Name         | Bit No.   |    | Description                       |  |  |
|------------------|---|----|-----------------------------------|--|--|
|                  |   |    | n-side switch open load condition |  |  |
| HS_OL            | OL 0  | 0: |                                   |  |  |
|                  |   | 1: | Open load at high side            |  |  |
| Bit indicates cu | Bit indicates current OL condition of high side (no flag) |    |                                   |  |  |

| SYS_STAT 0x2         | SYS_STAT 0x22 |      |          |             |      |      |      |      |  |
|----------------------|---------------|------|----------|-------------|------|------|------|------|--|
|                      | Bit7          | Bit6 | Bit5     | Bit4        | Bit3 | Bit2 | Bit1 | Bit0 |  |
| Default after<br>POR | 0             | 0    | 0        | 0           | 0    | 0    | 0    | 1    |  |
| Read                 | WD            | POR  | Testmode | SMPCLK_FAIL | 0    | EC2  | EC1  | EC0  |  |
| Write                | d.c.          | d.c. | d.c.     | d.c.        | d.c. | d.c. | d.c. | d.c. |  |

| Bit Name    | Bit No.   |                     | Description                   |  |  |  |
|-------------|---|---------------------|-------------------------------|--|--|--|
|             |   | Watchdog reset flag |                               |  |  |  |
| WD          | 7   | 0:                  |                               |  |  |  |
|             | 1:  |                     | Last reset caused by watchdog |  |  |  |
| Comment: Th | Comment: This flag is cleared after its content is transmitted to the master. |                     |                               |  |  |  |

Bit Name Bit No. Description

| Bit Name  | BIT NO. |                  | Description                          |  |  |  |  |
|---|---------|------------------|--------------------------------------|--|--|--|--|
|   |         | er-on reset flag |                                      |  |  |  |  |
| POR   | 6       | 0:               |                                      |  |  |  |  |
|   |         | 1:               | Last reset caused by a POR condition |  |  |  |  |
| Comment: This flag is cleared after its content is transmitted to the master. |         |                  |                                      |  |  |  |  |

| Bit Name    | Bit No.   |        | Description                                 |  |  |  |  |  |  |
|-------------|---|--------|---|--|--|--|--|--|--|
|             |   | lf thi | is bit is set, the device entered test mode |  |  |  |  |  |  |
| Testmode    | 5   | 0:     |   |  |  |  |  |  |  |
|             |   | 1:     | Device in Testmode                          |  |  |  |  |  |  |
| Comment: Th | Comment: This flag is cleared after its content is transmitted to the master and the device left the test mode. |        |   |  |  |  |  |  |  |

| Bit Name        | Bit No.   |        | Description   |  |  |  |  |  |  |
|-----------------|---|--------|---|--|--|--|--|--|--|
|                 |   | lf thi | s bit is set, the clock of the switch mode power supplies is too low. |  |  |  |  |  |  |
| SMPCLK_<br>FAIL | 4   | 0:     | Clock OK  |  |  |  |  |  |  |
| I AIL           |   | 1:     | Clock fail  |  |  |  |  |  |  |
| Comment: Th     | Comment: This flag is cleared after its content is transmitted to the master. |        |   |  |  |  |  |  |  |

 Bit Name
 Bit No.
 Description

 EC [2:0]
 0-2
 Actuarrow flag counter

 0:

 \*Error Counter is only deleted with a POR
 POR

#### XAS STRUMENTS

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# TPS65311-Q1

#### SLVSCA6A-OCTOBER 2013-REVISED OCTOBER 2013

| SPI_STAT 0x23       |      |      |      |      |      |            |             |             |
|---------------------|------|------|------|------|------|------------|-------------|-------------|
|                     | Bit7 | Bit6 | Bit5 | Bit4 | Bit3 | Bit2       | Bit1        | Bit0        |
| Default after RESET | 0    | 0    | 0    | 0    | 0    | 0          | 0           | 0           |
| Read                | 0    | 0    | 0    | 0    | 0    | CLOCK_FAIL | CMD_ID FAIL | PARITY FAIL |
| Write               | d.c. | d.c. | d.c. | d.c. | d.c. | d.c.       | d.c.        | d.c.        |

| Bit Name   | Bit No. | Description   |  |  |  |  |  |  |
|------------|---------|---|--|--|--|--|--|--|
|            |         | Between a falling and a rising edge of CSN, the number of SCK does not equal 16 |  |  |  |  |  |  |
| CLOCK_FAIL | 2       | 0:  |  |  |  |  |  |  |
|            |         | 1: Wrong SCK  |  |  |  |  |  |  |

Comment: This flag is cleared after its content is transmitted to the master.

| Bit No. | Description                             |  |  |  |  |  |
|---------|---|--|--|--|--|--|
|         | Last received CMD_ID in a reserved area |  |  |  |  |  |
| 1       | 0:                                      |  |  |  |  |  |
|         | 1: Wrong CMD_ID                         |  |  |  |  |  |
|         |   |  |  |  |  |  |

Comment: This flag is cleared after its content is transmitted to the master and is not set if the number of SCK cycles is incorrect.

| Bit Name        | Bit<br>No.  |      | Description                               |  |  |  |  |  |
|-----------------|---|------|---|--|--|--|--|--|
|                 | 0   | Last | received command has a parity bit failure |  |  |  |  |  |
| PARITY_FAIL     |   | 0:   |   |  |  |  |  |  |
|                 |   | 1:   | Parity bit error                          |  |  |  |  |  |
| Comment: This f | Comment: This flag is cleared after its content is transmitted to the master and is not set if the number of SCK cycles is incorrect. |      |   |  |  |  |  |  |

| COMP_STAT 0x24   |      |      |      |      |         |         |         |         |  |  |
|--|------|------|------|------|---------|---------|---------|---------|--|--|
|  | Bit7 | Bit6 | Bit5 | Bit4 | Bit3    | Bit2    | Bit1    | Bit0    |  |  |
| Default after<br>RESET   | 0    | 0    | 0    | 0    | 0       | 1       | 1       | 0       |  |  |
| Read   | 0    | 0    | 0    | 0    | BUCK3-1 | BUCK3-0 | BUCK2-1 | BUCK2-0 |  |  |
| Write  | d.c. | d.c. | d.c. | d.c. | d.c.    | d.c.    | d.c.    | d.c.    |  |  |
| Register to read back the actual BUCK2/3 compensation settings on COMP2/3. $0x1 \ge 0 V 0 x 2 \ge VREG 0 x 3 \ge open$ |      |      |      |      |         |         |         |         |  |  |

| DEV_REV 0x2F  |        |        |        |        |        |        |        |        |  |
|---|--------|--------|--------|--------|--------|--------|--------|--------|--|
|   | Bit7   | Bit6   | Bit5   | Bit4   | Bit3   | Bit2   | Bit1   | Bit0   |  |
| After RESET   | Major3 | Major2 | Major1 | Major0 | Minor3 | Minor2 | Minor1 | Minor0 |  |
| Read  | Major3 | Major2 | Major1 | Major0 | Minor3 | Minor2 | Minor1 | Minor0 |  |
| Write   | d.c.   |  |
| Hard coded device revision can be read from this register |        |        |        |        |        |        |        |        |  |

| PWR_CONFIG 0x31            |      |            |          |        |          |       |               |           |  |  |
|----------------------------|------|------------|----------|--------|----------|-------|---------------|-----------|--|--|
|                            | Bit7 | Bit6       | Bit5     | Bit4   | Bit3     | Bit2  | Bit1          | Bit0      |  |  |
| Default after RESET        | 0    | 1          | 1        | 0      | 1        | 0     | 0             | 0         |  |  |
| Read                       | 0    | BUCK2_EN   | BUCK3_EN | LDO_EN | BOOST_EN | HS_EN | GPFET_OV_HIGH | IRQ_THRES |  |  |
| Write                      | 0    | BUCK2_EN   | BUCK3_EN | LDO_EN | BOOST_EN | HS_EN | GPFET_OV_HIGH | IRQ_THRES |  |  |
| This register contains all |      | nahla hita |          |        |          |       |               |           |  |  |

This register contains all power rail enable bits.

| Bit Name | Bit No. | Description       |  |  |  |  |  |  |
|----------|---------|-------------------|--|--|--|--|--|--|
|          | 6       | BUCK2 enable flag |  |  |  |  |  |  |
| BUCK2_EN |         | 0:                |  |  |  |  |  |  |
|          |         | 1: Enable BUCK2   |  |  |  |  |  |  |

# TPS65311-Q1



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| Bit Name                      | Bit No. |  |  |  |  |
|-------------------------------|---------|--|--|--|--|
| After reset, BUCK2 is enabled |         |  |  |  |  |

Description

| Bit Name        | Bit No.                      |     | Description |  |  |  |  |  |
|-----------------|------------------------------|-----|-------------|--|--|--|--|--|
|                 |                              | LDO | enable flag |  |  |  |  |  |
| LDO_EN          | 4                            | 0:  |             |  |  |  |  |  |
|                 |                              | 1:  | LDO enabled |  |  |  |  |  |
| After reset, LD | After reset, LDO is disabled |     |             |  |  |  |  |  |

| Bit Name        | Bit No.                       |       | Description   |  |  |  |  |  |  |
|-----------------|-------------------------------|-------|---------------|--|--|--|--|--|--|
|                 |                               | BOOST | T enable      |  |  |  |  |  |  |
| BOOST_EN        | 3                             | 0:    |               |  |  |  |  |  |  |
|                 |                               | 1: B  | 300ST enabled |  |  |  |  |  |  |
| After reset, BO | After reset, BOOST is enabled |       |               |  |  |  |  |  |  |

| Bit Name          | Bit No.                            |     | Description                 |  |  |  |  |  |  |
|-------------------|------------------------------------|-----|-----------------------------|--|--|--|--|--|--|
|                   |                                    | LED | and high-side switch enable |  |  |  |  |  |  |
| HS_EN             | 2                                  | 0:  | High side disabled          |  |  |  |  |  |  |
|                   |                                    | 1:  | High side enabled           |  |  |  |  |  |  |
| After reset, high | After reset, high side is disabled |     |                             |  |  |  |  |  |  |

| Bit Name   | Bit<br>No. | Description   |  |  |  |  |  |
|--|------------|---|--|--|--|--|--|
|  |            | Protection FET overvoltage shutdown                         |  |  |  |  |  |
| GPFET_OV_HIGH  | 1          | 0: Protection FET switches off at VIN > V <sub>OVTH-L</sub> |  |  |  |  |  |
|  |            | 1: Protection FET switches off at VIN > V <sub>OVTH-H</sub> |  |  |  |  |  |
| After reset, the lower VIN protection threshold is enabled |            |   |  |  |  |  |  |

| Bit Name  | Bit No. | Description   |  |  |  |  |  |
|---|---------|---|--|--|--|--|--|
|   |         | VSSENSE IRQ low voltage interrupt threshold select    |  |  |  |  |  |
| IRQ_THRES   | 0       | 0: Low threshold selected (V <sub>SSENSETH_L</sub> )  |  |  |  |  |  |
|   |         | 1: High threshold selected (V <sub>SSENSETH_H</sub> ) |  |  |  |  |  |
| After reset, the lower VBAT monitoring threshold is enabled |         |   |  |  |  |  |  |

#### DEV CONFIG 0x32

| DEV_CONFIG 0X32     |      |      |      |      |      |       |      |      |
|---------------------|------|------|------|------|------|-------|------|------|
|                     | Bit7 | Bit6 | Bit5 | Bit4 | Bit3 | Bit2  | Bit1 | Bit0 |
| Default after RESET | 0    | 0    | 0    | 0    | 0    | 1     | 1    | 0    |
| Read                | 0    | 0    | 0    | 0    | 0    | VT_EN | RSV  | RSV  |
| Write               | d.c. | d.c. | d.c. | d.c. | d.c. | VT_EN | 1    | 0    |

| Bit Name | Bit No. | Description  |  |  |  |  |  |  |
|----------|---------|--|--|--|--|--|--|--|
|          |         | LED and high-side switch current limit counter disable bit |  |  |  |  |  |  |
| HS_CLDIS | 3       | 0: LED and high-side switch current limit counter enabled  |  |  |  |  |  |  |
|          |         | 1: LED and high-side switch current limit counter disabled |  |  |  |  |  |  |



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| Bit Name | Bit No. | Description            |  |  |  |  |  |  |
|----------|---------|------------------------|--|--|--|--|--|--|
|          |         | VT enable bit          |  |  |  |  |  |  |
| VT_EN    | 2       | 0: VT monitor disabled |  |  |  |  |  |  |
|          |         | 1: VT monitor enabled  |  |  |  |  |  |  |

The VT monitor cannot be turned on after it was turned off. Turn on only happens during power up in the VTCHECK state.

| Bit Name | Bit No. |       | Description              |  |  |  |  |  |  |
|----------|---------|-------|--------------------------|--|--|--|--|--|--|
|          |         | Volta | age reference enable bit |  |  |  |  |  |  |
| RSV      | 1       | 0:    | not recommended setting  |  |  |  |  |  |  |
|          |         | 1:    | default setting          |  |  |  |  |  |  |

| Bit Name | Bit No. | Description                  |  |  |  |  |  |  |
|----------|---------|------------------------------|--|--|--|--|--|--|
|          |         | eserved - keep this bit at 1 |  |  |  |  |  |  |
| RSV      | 0       | default setting              |  |  |  |  |  |  |
|          |         | not recommended setting      |  |  |  |  |  |  |

#### CLOCK\_CONFIG 0x33

|                        | AUU  |       |         |      |      |      |      |      |
|------------------------|------|-------|---------|------|------|------|------|------|
|                        | Bit7 | Bit6  | Bit5    | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
| Default after<br>RESET | 0    | 0     | 0       | 1    | 0    | 0    | 0    | 0    |
| Read                   | F_EN | SS_EN | SS_MODE | F4   | F3   | F2   | F1   | F0   |
| Write                  | F_EN | SS_EN | SS_MODE | F4   | F3   | F2   | F1   | F0   |

| Bit Name | Bit No.   |    | Description  |  |  |  |  |  |  |  |
|----------|-----------|----|--|--|--|--|--|--|--|--|
|          | Frequency |    | quency tuning enable register  |  |  |  |  |  |  |  |
| F_EN     | 7         | 0: | Off - Setting of Bit4Bit0 are not effective, setting of Bit6 and Bit5 become effective |  |  |  |  |  |  |  |
|          |           | 1: | On – Setting of Bit4Bit0 become effective, setting of Bit6 and Bit5 are not effective  |  |  |  |  |  |  |  |

| Bit Name   | Bit No. |    | Description  |  |  |  |  |  |  |  |  |  |
|--|---------|----|--|--|--|--|--|--|--|--|--|--|
| Spread spectrum mode enable  |         |    |  |  |  |  |  |  |  |  |  |  |
| SS_EN  | 6       | 0: | Spread spectrum option for all switching regulators disabled                     |  |  |  |  |  |  |  |  |  |
|  |         | 1: | Spread spectrum option for all switching regulators enabled (only when F_EN = 0) |  |  |  |  |  |  |  |  |  |
| When enabled, the switching frequency of BLICK1/2/3 and BOOST is modulated between 0.8xfare and fare |         |    |  |  |  |  |  |  |  |  |  |  |

When enabled, the switching frequency of BUCK1/2/3 and BOOST is modulated between 0.8×f<sub>osc</sub> and f<sub>osc</sub>

| Bit Name | Bit No. | Description  |  |  |  |  |  |  |  |  |  |
|----------|---------|--|--|--|--|--|--|--|--|--|--|
|          |         | read spectrum mode select (effective only when F_EN = 0) |  |  |  |  |  |  |  |  |  |
| SS_MODE  | 5       | Pseudo random  |  |  |  |  |  |  |  |  |  |
|          |         | Triangular   |  |  |  |  |  |  |  |  |  |

| Bit Name Bit No. Description   |  |  |  |  |  |  |  |  |
|--|--|--|--|--|--|--|--|--|
| F4, F3, F2, F1,<br>F04-0Frequency tuning register (effective only when F_EN = 1)   |  |  |  |  |  |  |  |  |
| 0x10 is default value, trim range is 25% for 0x00 setting to -20% for 0x1F setting. Frequency tuning influences the switching frequency of BUCK1/2/3 and BOOST as well as the watchdog timing. |  |  |  |  |  |  |  |  |

#### SLVSCA6A-OCTOBER 2013-REVISED OCTOBER 2013

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#### **REVISION HISTORY**

| Changes from Original (October 2013) to Revision A |  |
|--|--|

| • | Changed document status from Product Preview to Production Data  | 1  |
|---|--|----|
| • | Deleted both min values (-44°C and -55°C) for T <sub>J</sub> in the RECOMMENDED OPERATING CONDITIONS table   |    |
| • | Changed both max values for T <sub>J</sub> from 150°C to 125°C in the RECOMMENDED OPERATING CONDITIONS table   | 4  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 5  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 6  |
| • | Changed one test condition for the $V_{Droupout}$ parameter in the <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J = 150^{\circ}C$ to $T_J = 125^{\circ}C$                                     | 6  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 7  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)}$ = 125°C  | 8  |
| • | Deleted the T <sub>J</sub> temperature range from SHUTDOWN COMPARATOR subheader row in the <i>ELECTRICAL</i> CHARACTERISTICS table   | 8  |
| • | Changed one test condition for the $I_{VT\_leak}$ parameter in the <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J = -20^{\circ}C$ to $150^{\circ}C$ to $T_J = -20^{\circ}C$ to $125^{\circ}C$ | 8  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 9  |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 10 |
| • | Changed the T <sub>J</sub> temperature range to $T_{J(max)}$ = 125°C for the INTERNAL VOLTAGE REGULATORS subheader row in the <i>ELECTRICAL CHARACTERISTICS</i> table                            | 10 |
| • | Changed condition statement of <i>ELECTRICAL CHARACTERISTICS</i> table from $T_J$ temperature range to $T_{J(max)} = 125^{\circ}C$   | 11 |



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### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp       | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|---------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty     | (2)                        | (6)              | (3)                 |              | (4/5)          |         |
| TPS65311QRVJRQ1  | ACTIVE | VQFN         | RVJ     | 56   | 2000    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR | -40 to 125   | TPS65311       | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

19-Oct-2013

# PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal |                 |                    |    |      |                          |                          |            |            |            |            |           |                  |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                      | Package<br>Type | Package<br>Drawing |    |      | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| TPS65311QRVJRQ1             | VQFN            | RVJ                | 56 | 2000 | 330.0                    | 16.4                     | 8.3        | 8.3        | 2.25       | 12.0       | 16.0      | Q2               |

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# PACKAGE MATERIALS INFORMATION

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\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS65311QRVJRQ1 | VQFN         | RVJ             | 56   | 2000 | 367.0       | 367.0      | 38.0        |

# **MECHANICAL DATA**



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) Package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. F. Package complies to JEDEC MO-220.
- Slot/Dimple added to external leads.



# <u>RVJ (S-PVQFN-N56)</u>

# PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters



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